

BAT32A239 Datasheet

Ultra-low power 32-bit microcontroller based on ARM® Cortex-M0®+

Built-in 256K bytes Flash, rich analog functions, timers and various communication interfaces

V1.0.7

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Function

- Ultra-low power operating environment:
 - Supply voltage range: 2.0V to 5.5V
 - ➢ Temperature range: -40°C to 125°C
 - Low power modes: sleep mode, deep sleep mode
 - Operating power consumption: 120uA/MHz @64MHz
 - Power consumption in deep sleep mode: 0.8uA
 - Deep sleep mode +32.768K + RTC operation: 1.2uA

• Kernel:

- ARM®32-bitCortex®-M0+ CPU
- > Operating frequency: 32KHz to 64MHz

• Memory:

- 256KB Flash memory, program shared with data storage
- > 2.5KB dedicated data flash memory
- > 32KB SRAM MEMORY WITH PARITY

• Power and reset management:

- Built-in power-on reset (POL) circuitry
- Built-in voltage detection (LVD) circuit (threshold voltage can be set).

Clock Management:

- Built-in high-speed oscillator, accuracy (±1%). A 1 MHz to 64MHz system clock and peripheral module action clock are available
- Built-in 15KHz low-speed oscillator
- Built-in 1 channel PLL
- Support 1MHz ~ 20MHz external crystal oscillator, support stop vibration monitoring
- Supports 32.768KHz external crystal oscillator for correction of internal highspeed oscillators

• Multiplier/Divider Module:

- Multiplier: Supports single-cycle 32bit multiplication operations
- Divider: Supports 32bit signed integer division and requires only 8 CPU clock cycles to complete the operation

• Enhanced DMA controller:

- > An interrupt triggers a start.
- Transfer modes selectable (normal transfer mode, repeat transfer mode, block transfer mode, and chain transfer

• Rich analog periphery:

- 12-bit precision ADC converter with 1.42Msps slew rate, 21 external analog channels, internal selectable PGA output as the conversion channel, temperature sensor, and support for single-channel conversion mode and multi-channel sweep conversion mode. Conversion range: 0 to positive reference voltage
- 8-bit precision D/A converter, 2-channel analog output, real-time output function, output voltage range 0~V_{DD}
- Comparator (CMP) with built-in two-channel hysteresis comparator, selectable input source, and selectable external reference or internal reference voltage reference
- Programmable gain amplifier (PGA) with two channels of PGA to program 4/8/10/12/14/16/32 gains with an external GND pin that can be used as differential mode

Input/output port:

- I/O ports: 45 to 75
- Capable of N-channel open-drain, TTL input buffering, and internal pull-up switching
- Built-in key interrupt check-out function
- Control circuitry with built-in clock output/buzzer output
- Serial two-wire debugger (SWD).
- Rich timers:
 - 16-bit timer: 17 channels (with PWM function and motor dedicated PWM function).
 - 15-bit interval timer: 1
 - Real-time clock (RTC): 1 (with perpetual calendar, alarm clock function, and support for a wide range of clock correction).
 - Watchdog timer (WWDT): 1
 - SysTick timer

Rich and flexible interfaces:

3 serial communication unit: Serial communication unit 0 can be freely configured as 2-channel standard UART or 4channel 3-wire SPI or 4-channel simple I²C; Serial communication unit 1 or 2 can be freely configured as 1-channel standard UART or 2-channel 3-wire SPI or 2-channel simple I²C; (UART of unit 0 supports LIN Bus communication, SPI00 channel supports 4-



mode)

The source/destination field is optional for full address space range

• Linkage Controller:

- It can link event signals together to achieve the linkage of peripheral functions.
- There are 23 types of event inputs and 10 types of event triggers.

wire SPI communication)

- Standard I²C: 2 channels
- CAN: 2 channels

Security features:

- Complies with IEC/UL 60730 related standards
- Abnormal storage space access error is reported
- Supports RAM parity
- Supports hardware CRC verification
- Supports critical SFR protection against misoperation
- > 128-bit unique ID number
- Flash secondary protection in debug mode (level1: only flash full domain erasure, can not read and write; level2: The emulator connection is invalid and cannot be operated on flash).
- Package:
 - Support 48Pin, 64Pin, 80Pin multiple packages



1 Overview

1.1 Brief Introduction

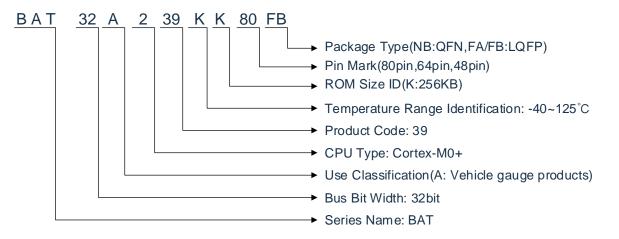
BAT32A239 series conforms to AEC-Q100 Grade1 automotive product standard, -40~125 °C operating ambient temperature, support 48~80Pin in a variety of LQFP packages. This product uses the 32bit of the high-performance ARM®Cortex-M0®+ RISC core, operating up to 64MHz, uses high-speed embedded flash memory (SRAM up to 32KB, program/data flash up to 256KB). Integrated I²C, SPI, UART, LIN, and CAN bus and other standard interfaces. Integrated 12bit A/D converter, temperature sensor, 8bit D/A converter, comparator, programmable gain amplifier. The 12bit A/D converter can acquire external sensor signals to reduce system design costs. The 8bit D/A converter can be used for audio playback or power control. An integrated on-chip temperature sensor enables real-time monitoring of the external ambient temperature. An integrated comparator is included in the chip for applications such as control feedback from running motors or battery monitoring. Integrate a variety of advanced timer modules, load 1-channel SysTick timer, 17-channels 16 Features such as bit timer, 1-channel 15bit interval timer, watchdog timer, and real-time clock support for general-purpose PWM and motor specific PWM and other applications.

The BAT32A239 also features excellent low-power performance, supporting both sleep and deep sleep lowpower modes for flexible design. It consumes 120uA/MHz @64MHz and consumes only 0.8uA in deep sleep mode for battery-powered, low-power devices. At the same time, due to the integrated event linkage controller, it can realize the direct connection between hardware modules, without CPU intervention, faster than using interrupt response, while reducing the frequency of CPU activity and prolonging battery life.

The reliability of the BAT32A239 microcontroller family, rich integrated peripheral functions, and excellent low power consumption make them suitable for a wide range of automotive product development.



1.2 List of Product Models



Product List for BAT32A239 :

Number of pins	Package	Product model		
19 pipe	48-pin plastic LQFP (7x7mm, 0.5mm pitch).	BAT32A239KK48FA		
48 pins	48-pin plastic QFN (6x6mm, 0.4mm pitch).	BAT32A239KK48NB		
64 pins	64-pin plastic LQFP (7x7mm, 0.4mm pitch).	BAT32A239KK64FB		
80 pins	80-pin plastic LQFP (12x12mm, 0.5mm pitch).	BAT32A239KK80FA		

FLASH, SRAM capacity:

Flash	Specific data	SRAM		2A239		
memory	flash memory	SKAIVI	48 p	ins	64 pins	80 pins
256KB	2.5 KB	32KB	BAT32A239KK48FA	BAT32A239KK48NB	BAT32A239KK64FB	BAT32A239KK80FA



Product Selection Table for BAT32A239:

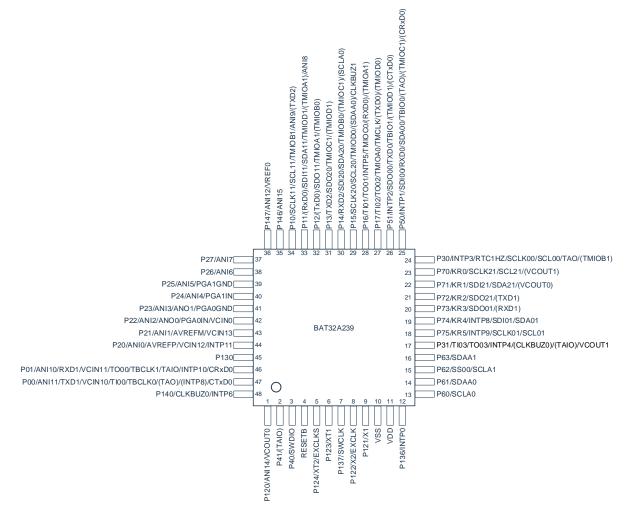
Part No.	Kernel	Frequency (MHz)	Minimum operating voltage (V).	Maximum operating voltage (V).	Code flash (kB)	SRAM (kB)	Data flash (kB)	DMA	GPIO	12bit ADC	8bit DAC	Comparator CMP	Amplifier PGA	Universal timer (16bit).	Real-time clock (RTC).	Watchdog timer (WDT).	Asynchronous serial bus (UART).	Synchronous serial bus (SPI).	IIC bus	LIN bus	CAN bus	Hardware multiplier	Hardware divider	Package
BAT32A239 KK48FA	M0+	64	2.0	5.5	256	32	2.5	36	45	15+ 4	2	2	2	17	1	1	3	5	2+5	1	1	Y	Y	LQFP 48
BAT32for239 KK48NB	M0+	64	2.0	5.5	256	32	2.5	36	45	15+ 4	2	2	2	17	1	1	3	5	2+5	1	1	Y	Y	QFN 48
BAT32A239 KK64FB	M0+	64	2.0	5.5	256	32	2.5	37	59	16+ 4	2	2	2	17	1	1	3	6	2+6	1	1	Y	Y	LQFP 64
BAT32A239 KK80FA	M0+	64	2.0	5.5	256	32	2.5	37	75	21+ 4	2	2	2	17	1	1	4	8	2+8	1	2	Y	Y	LQFP 80



1.3 Top View

1.3.1 BAT32A239KK48FA

• 48-pin plastic LQFP (7x7mm, 0.5mm pitch).

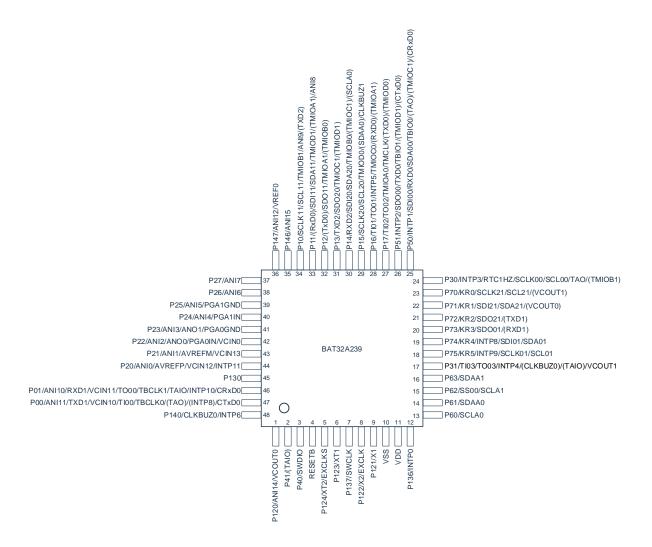


Note: The functions in () of above Figure can be assigned by setting the peripheral I/O redirection registers.



1.3.2 BAT32A239KK48NB

• 48-pin plastic QFN48 (6x6mm, 0.4mm pitch).

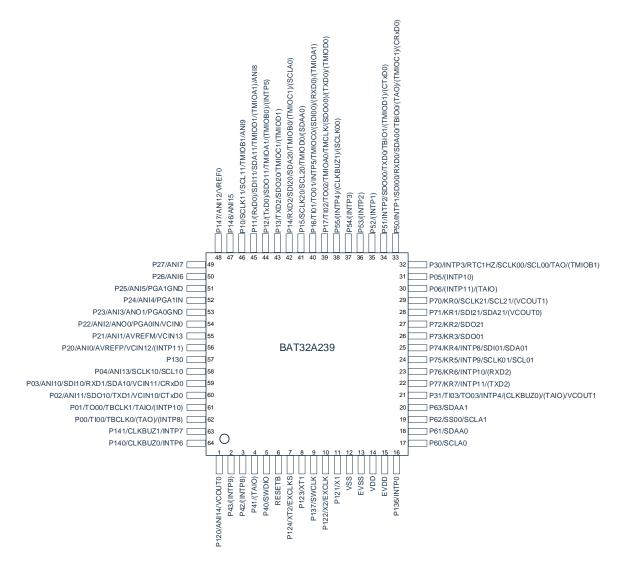


Note: The functions in () of above Figure can be assigned by setting the peripheral I/O redirection registers.



1.3.3 BAT32A239KK64FB

• 64-pin plastic LQFP (7x7mm, 0.4mm pitch).

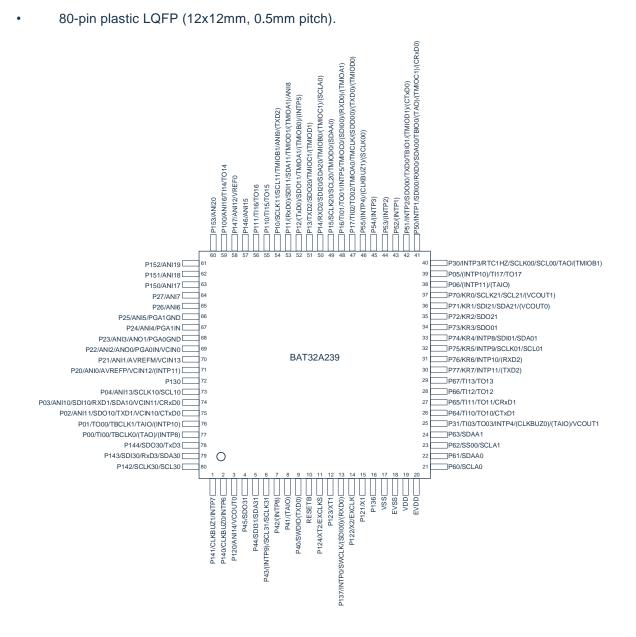


Note:

- 1. The EVss pin and the Vss pin must be in the same potential.
- 2. The voltage at the V_{DD} pin must be equal to the voltage at the EV_{DD} pin.
- In the case of application areas where it is necessary to reduce the noise generated from the inside of the microcontroller, noise countermeasures such as providing separate power to V_{DD} and EV_{DD} and grounding V_{SS} and EV_{SS} separately are recommended.
- 4. The functions in the preceding figure () can be assigned by setting the peripheral I/O redirection registers.



1.3.4 BAT32A239KK80FA

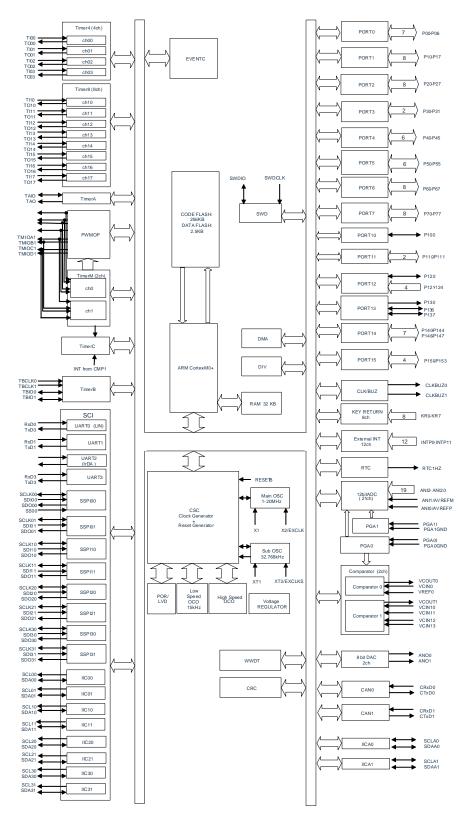


Note:

- 1. The EV_{SS} pin and the V_{SS} pin must be in the same potential.
- 2. The voltage at the V_{DD} pin must be equal to the voltage at the EV_{DD} pin.
- In the case of application areas where it is necessary to reduce the noise generated from the inside of the microcontroller, noise countermeasures such as providing separate power to V_{DD} and EV_{DD} and grounding V_{SS} and EV_{SS} separately are recommended.
- 4. The functions in the preceding figure () can be assigned by setting the peripheral I/O redirection registers.



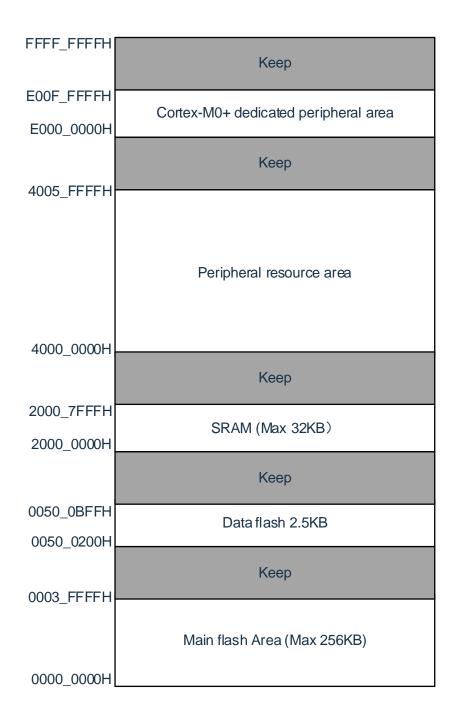
2 Product Structure Diagram



Note: The above figure is a block diagram of an 80-pin product, and some functions of products below 80 pin are not supported.



3 Memory Mapping





4 Pin Function

4.1 **Port Functionality**

The relationship between the power supply and the pin is shown below

80-pin, 64-pin product:

Power/Ground	The Corresponding Pin			
EV _{DD} /EV _{SS}	Port pins other than P20~P27, P121~P124, P137 and RESETB			
VDD/Vss	• P20~P27, P121~P124, P137 and RESETB			

The 48-pin product uses a single power supply, and all pins are powered by V_{DD} .

All ports of this product are divided into five types by type, which are type1 to type5, and the corresponding conditions are as follows:

Type 1: Bidirectional I/O function

Type 2: NOD function, corresponding to pin P60-P63

Type 3: Only input functions, such as clocks, correspond to pins P121-P124

Type 4: Output function only, corresponding to pin P130

Type 5: RESET function, corresponding to pin RESETB

For details of the lead frame diagrams for each type, see 4.3 Port types



4.1.1 48 Pin Product Pin Function Description

					(1/2)							
The feature	Port type	Input / output	After the reset is	Multiplexing function	Function							
name			released									
P00				ANI11/TXD1/VCIN10/TI00/TBCLK0/(TAO)	Port 0							
				/(INTP8)/CTxD0	2-bit input/output port, which can be							
					specified as input or output in bits. The							
					input port can be set by software							
		Input /	Analog		using an internal pull-up resistor.							
		output	function	ANI10/RXD1/VCIN11/TO00/TBCLK1	The input of P01 can be set to TTL							
P01				/TAIO/INTP10/CRxD0	input buffering. The output of P00 can							
					be set to an N-channel open-drain							
					output (V _{DD} withstand voltage).							
					P00 and P01 can be set to analog							
					inputs.							
P10			Analog	SCLK11/SCL11/TMIOB1/ANI9/(TXD2)	Port 1							
P11			function	(RxD0)/SDI11/SDA11/TMIOD1/(TMIOA1)/ANI8	An 8-bit input /output port that can be							
P12						(TxD0)/SDO11/TMIOA1/(TMIOB0)	specified as an input or output in bits.					
P13				TxD2/SDO20/TMIOC1/(TMIOD1)	The input port can be set by software							
P14				RxD2/SDI20/SDA20/ TMIOB0/(TMIOC1)/	using an internal pull-up resistor							
1 17		Input / output		(SCLA0)	The inputs for P10 and P14~ P17 can							
P15	Туре		-					SCLK20/SCL20/TMIOD0/(SDAA0)/CLKB	be set to TTL Input buffering.			
1 10	1						output	output	output	ouipui	output	Input port
P16				TI01/TO01/INTP5/TMIOC0/(RXD0)/(TMIOA1	and P17 can be programmed to N-							
110)	channel open-drain outputs (V _{DD}							
				TI02/TO02/TMIOA0/TMCLK/(TXD0)	Withstand pressure).							
P17				/(TMIOD0)	P10 and P11 can be set to analog							
					inputs.							
P20				ANI0/AVREFP/VCIN12/INTP11	_							
P21				ANI1/AVREFM/VCIN13								
P22				ANI2/ANO0/PGA0IN/VCIN0	Port 2							
P23		Input /	Analog	ANI3/ANO1/PGA0GND	An 8-bit input /output port that can be							
P24		output	function	ANI4/PGA1IN	specified as an input or output in bits.							
P25				ANI5/PGA1GND	Can be set to analog input.							
P26				ANI6								
P27				ANI7								
P30				INTP3/RTC1HZ/SCLK00/SCL00/TAO	Port 3							
P30		loout /		/(TMIOB1)	2-bit input/output port, can be specified							
P31		Input / output	Input port	TI03/TO03/INTP4/(CLKBUZ0)/(TAIO) /VCOUT1	as input or output in bits. The input port can be set by software using an internal pull-up resistor							



					The input of the P30 can be set to TTL
					input buffering. The output of the P30
					can be set to an N-channel open-drain
					output (V_{DD} withstand voltage).
P40				SWDIO	Port 4
		Input /			2-bit input/output port, can be specified
P41		output	Input port	(TAIO)	as input or output in bits. The input port
F41		output		(140)	can be set by software using an
					internal pull-up resistor.



(2/2)

			After the		(2/2)			
Function	Port	Input /	After the reset is	Multiplexing function	Function			
name	type	output	released					
P50				INTP1/SDI00/RXD0/SDA00/TBIO0/(TAO) /(TMIOC1)/(CRxD0)	Port 5 2-bit input/output port, which can be			
P51	Type 1	Input / output	Input port	INTP2/SDO00/TXD0/TBIO1/(TMIOD1)/(CT xD0)	specified as input or output in bits. The input port can be set by software using an internal pull-up resistor. The input of the P50 can be set to TTL input buffering. The outputs of P50 and P51 can be set to N-channel open-drain outputs (V_{DD} withstand voltage).			
P60				SCLA0	Port 6			
P61	Turne O	Input /	locut port	SDAA0	A 4-bit input /output port that can be			
P62	Type 2	output	Input port	SS00	specified as an input or output in bits. The output of P60 to P63 is an N-channel			
P63				—	open-drain output (6V withstand voltage).			
P70			Input port	KR0/SCLK21/SCL21/(VCOUT1)	Port 7			
P71				KR1/SDI21/SDA21/(VCOUT0)	A 6-bit input/output port that can be specified as an input or output in bits.			
P72		Input /		KR2/SDO21/(TXD1)	The input port can be set by software			
P73	Type 1	output		KR3/SDO01/(RXD1)	using an internal pull-up resistor. The			
P74	турет			KR4/INTP8/SDI01/SDA01	outputs of P71 and P74 can be			
P75				KR5/INTP9/SCLK01/SCL01	programmed to N-channel open-drain outputs (V _{DD} withstand voltage).			
P120		Input / output	Analog function	ANI14/VCOUT0	Port 12 1-bit input /output port and 4-bit input			
P121				X1	dedicated port.			
P122				X2/EXCLK	Only the P120 has an output function. Only the input port of the P120 can be set by software to use the internal pull-up			
P123	Type 3	input	Input port	XT1				
P124				XT2/EXCLKS	resistor. The P120 can be set to an analog input.			
P130	Type 4	output	Output port		Port 13 1-bit output dedicated ports and 2-bit			
P136				INTP0	input/output ports, P136 and P137 can be			
P137		Input/ output	Input port	SWCLK	specified as inputs or outputs in bits. The input port can be set by software using internal pull-up resistors.			
P140	Type 1		Input port	CLKBUZ0/INTP6	Port 14			
P146	iype i	Inc		ANI15	A 3-bit input /output port that can be			
P147		Input/ output	Analog function	ANI12/VREF0	specified as an input or output in bits. The input port can be set by software using an internal pull-up resistor. P146, P147 can be set to analog input.			
RESETB	Туре 5	input	_	_	Input-specific pin for external reset When no external reset is used, it must be connected to the V _{DD} directly or via a resistor.			

Note:

1. Set each pin to digital or analog (can be set in bits) via port mode control register x (PMCx).

- 2. For a description of the multiplexing function, see "4.2 Port Multiplexing Function".
- 3. The functions in Table () above can be assigned by setting the peripheral I/O redirection registers.



4.1.2 64 Pin Product Pin Function Description

(1/2)

					(1/2		
Function name	Port type	Input / output	After the reset is released	Multiplexing function	Description of the feature		
P00				TI00/TBCLK0/(TAO)/(INTP8)	Port 0		
P01			Input port	TO00/TBCLK1/TAIO/(INTP10)	A 7-bit input/output port that can be		
P02				ANI11/SDO10/TXD1/VCIN10/CTxD0	specified as an input or output in bits. The		
			Analog	ANI10/SDI10/RXD1/SDA10/VCIN11/CRx	input port can be set by software using		
P03			function	function	D0	an internal pull-up resistor.	
P04		Input /		ANI13/SCLK10/SCL10	The inputs for P01, P03, and P04 can be		
P05		output		(INTP10)	set to TTL Input buffering.		
					The outputs of P00 and P02~ P04 can be		
			Input part		set to N-channel open-drain output (EV $_{\mbox{\scriptsize DD}}$		
P06			Input port	(INTP11)/(TAIO)	withstand voltage).		
					P02, P03, P04 can be set as analog		
					inputs.		
P10			Analog	SCLK11/SCL11/TMIOB1/ANI9	Dort 1		
P11				function	(RxD0)/SDI11/SDA11/TMIOD1/(TMIOA1)/	Port 1 An 8-bit input/output port that can be	
				ANI8	specified as an input or output in bits. The		
P12				(TxD0)/SDO11/TMIOA1/(TMIOB0)/(INTP5	input port can be set by software using		
112)	an internal pull-up resistor.		
P13	T	Input /		TXD2/SDO20/TMIOC1/(TMIOD1)	The inputs for P10 and P14~ P17 can be		
P14		Type 1	output	-		RXD2/SDI20/SDA20/TMIOB0/(TMIOC1)/	set to TTL
1 14	1	output			(SCLA0)	Input buffering.	
P15			input port	SCLK20/SCL20/TMIOD0/ (SDAA0)	The outputs of P10, P11, P13~P15, and P17		
P16				TI01/TO01/INTP5/TMIOC0/(SDI00)/	can be set to N-channel open-drain output		
110				(RXD0)/(TMIOA1)	(EV _{DD} withstand voltage).		
P17				TI02/TO02/TMIOA0/TMCLK/(SDO00) /(TXD0)/(TMIOD0)	P10 and P11 can be set to analog inputs.		
P20				ANI0/AVREFP/VCIN12/(INTP11)			
P21				ANI1/AVREFM/VCIN13			
P22				ANI2/ANO0/PGA0IN/VCIN0	Port 2		
P23		Input /	Analog	ANI3/ANO1/PGA0GND	An 8-bit input/output port that can be		
P24		output	function	ANI4/PGA1IN	specified as an input or output in bits. Can		
P25				ANI5/PGA1GND	be set to analog input.		
P26				ANI6			
P27				ANI7			
Det				INTP3/RTC1HZ/SCLK00/SCL00/TAO	Port 3		
P30		Input /		/(TMIOB1)	2-bit input/output port, which can be		
		output	Input port		1		
P31		output		TI03/TO03/INTP4/(CLKBUZ0)/(TAIO)	specified as input or output in bits. The		



		an internal pull-up resistor.
		The input of the P30 can be set to TTL
		input buffering. The output of the P30 can
		be set to an N-channel open-drain output
		(EV _{DD} withstand voltage).

					(2/2)			
Function name	Port type	Input / output	After the reset is released	Multiplexing function	Function			
P40				SWDIO	Port 4			
P41		Input /		(TAIO)	A 4-bit input/output port that can be			
P42		output	Input port	(INTP8)	specified as an input or output in bits. The			
P43				(INTP9)	input port can be set by software using an internal pull-up resistor.			
P50				INTP1/SDI00/RXD0/SDA00/TBIO0/ (TAO) /(TMIOC1)/(CRxD0)	Port 5 A 6-bit input/output port that can be			
P51	Type 1			INTP2/SDO00/TXD0/TBIO1/(TMIOD1)/(CTxD0)	specified as an input or output in bits. The input port can be set by software using an			
P52		Input /		(INTP1)	internal pull-up resistor.			
P53		output	Input port	(INTP2)	The inputs of P50 and P55 can be set to			
P54				(INTP3)	TTL input buffers.			
P55				(INTP4)/(CLKBUZ1)/(SCLK00)	The outputs of the P50, P51, and P55 can be set to N-channel open-drain output (EV _{DD} withstand voltage).			
P60							SCLA0	Port 6
P61		Input /		SDAA0	A 4-bit input/output port that can be			
P62	Type 2	output	Input port	SS00/SCLA1	specified as an input or output in bits.			
P63				SDAA1	The output of P60 to P63 is an N-channel open-drain output (6V withstand voltage).			
P70				KR0/SCLK21/SCL21/(VCOUT1)	Port 7			
P71				KR1/SDI21/SDA21/(VCOUT0)	An 8-bit input/output port that can be			
P72				KR2/SDO21	specified as an input or output in bits. The			
P73		Input /	Input port	KR3/SDO01	input port can be set by software using an			
P74	Type 1	output	input port	KR4/INTP8/SDI01/SDA01	internal pull-up resistor.			
P75	турет			KR5/INTP9/SCLK01/SCL01	The outputs of the P71 and P74 can be			
P76				KR6/INTP10/(RxD2)	set to N-channel open-drain output (EV_{DD}			
P77				KR7/INTP11/(TxD2)	withstand voltage).			
P120		Input / output	Analog function	ANI14/VCOUT0	Port 12 1-bit input /output port and 4-bit input			
P121				X1	dedicated port			
P122	Туре 3	input	Input port	X2/EXCLK	Only P120 can specify inputs or outputs.			
P123				XT1	Only the input port of the P120 can be set			



					by software to use the internal pull-up			
P124				XT2/EXCLKS	resistor. The P120 can be set to an analog			
					input.			
D120	Turna 4	output	Output		Port 13			
P130	туре 4	output	port	—	1-bit output dedicated port and 2-bit			
P136				INTP0	input/output port, P136 and P137 can be			
		output	Input port		specified as input or output in bits. The			
P137			Input port	SWCLK	input port can be set by software using			
						internal pull-up resistors.		
P140			land a set	CLKBUZ0/INTP6	Port 14			
P141	Type 1		Input port	CLKBUZ1/INTP7	4-bit input/output port, can be specified as			
P146		Input /	Input /	Input /	Input /		ANI15	input or output in bits. The input port can
		output	Analog		be set by software using an internal pull-			
P147			function	ANI12/VREF0	up resistor.			
					P146, P147 can be set to analog input.			
					An input pin dedicated to an external reset			
RESETB	Type 5	input	_		must be connected to V_{DD} directly or via a			
					resistor when no external reset is used.			

Note:

- 1. Set each pin to digital or analog (can be set in bits) via port mode control register x (PMCx).
- 2. For a description of the multiplexing function, see "4.2 Port Multiplexing Function".
- 3. The functions in Table () above can be assigned by setting the peripheral I/O redirection registers.



4.1.3 80 Pin Product Pin Function Description

(1/2)

	-				
Function name	Port type	Input / output	After the reset is released	Multiplexing function	Description of the feature
P00				TI00/TBCLK0/(TAO)/(INTP8)	Port 0
P01			Input port	TO00/TBCLK1/TAIO/(INTP10)	A 7-bit input /output port that can be
P02		Input /		ANI11/SDO10/TXD1/VCIN10/CTxD0	specified as an input or output in bits. The
Dee			Analog	ANI10/SDI10/RXD1/SDA10/VCIN11/CR	input port can be set by software using
P03			function	xD0	an internal pull-up resistor.
P04			Input /		ANI13/SCLK10/SCL10
P05		output		(INTP10)/TI17/TO17	set to TTL
					Input buffering.
			Input part		The outputs of P00 and P02~ P04 can be
P06			Input port	(INTP11)/(TAIO)	set to N-channel open-drain output (EV $_{\mbox{\scriptsize DD}}$
					withstand voltage).
					P02, P03, P04 can be set as analog inputs
P10			Analog	SCLK11/SCL11/TMIOB1/ANI9/(TXD2)	
P11			function	(RxD0)/SDI11/SDA11/TMIOD1/(TMIOA1)	Port 1
				/ANI8	An 8-bit input/output port that can be
P12				(TxD0)/SDO11/TMIOA1/(TMIOB0)/(INT	specified as an input or output in bits. The
1 12				P5)	input port can be set by software using
P13				TXD2/SDO20/TMIOC1/(TMIOD1)	an internal pull-up resistor.
P14	Type 1	Input /		RXD2/SDI20/SDA20/TMIOB0/(TMIOC	The inputs for P10 and P14~ P17 can be
F 14		output		1)/(SCLA0)	set to TTL
P15			Input port	SCLK20/SCL20/TMIOD0/	Input buffering.
115				(SDAA0)	The outputs of P10, P11, P13~P15, and P17
P16				TI01/TO01/INTP5/TMIOC0/(SDI00)/	can be set to N-channel open-drain output
FIU				(RXD0) /(TMIOA1)	(EV _{DD} withstand voltage).
P17				TI02/TO02/TMIOA0/TMCLK/(SDO0	P10 and P11 can be set to analog inputs.
				0) /(TXD0)/(TMIOD0)	
P20				ANI0/AVREFP/VCIN12/(INTP11)	
P21				ANI1/AVREFM/VCIN13	
P22				ANI2/ANO0/PGA0IN/VCIN0	Port 2
P23		Input /	Analog	ANI3/ANO1/PGA0GND	An 8-bit input /output port that can be
P24		output	function	ANI4/PGA1IN	specified as an input or output in bits. Can
P25				ANI5/PGA1GND	be set to analog input.
P26				ANI6	
P27]			ANI7	
Daa				INTP3/RTC1HZ/SCLK00/SCL00/TAO	Port 3
P30		Input /	Input port	/(TMIOB1)	2-bit input/output port, which can be
P31	1	output		TI03/TO03/INTP4/(CLKBUZ0)/(TAIO	specified as input or output in bits. The
				20 / 80	Boy 107



)	input port can be set by software using
	/VCOUT1	an internal pull-up resistor.
		The input of the P30 can be set to TTL
		input buffering. The output of the P30 can
		be set to an N-channel open-drain output
		(EV _{DD} withstand voltage).

Function name	Port type	Input / output	After the reset is released	Multiplexing function	Function	
P40			SWDIO(TXD0)	Port 4		
P41				(TAIO)	A 6-bit input /output port that can be	
P42				(INTP8)	specified as an input or output in bits.	
P43		Input /	Input port	(INTP9)/SCLK31/SCL31	The input port can be set by software	
P44		output		SDA31/SDI31	using an internal pull-up resistor.	
P45		σαιραι		SDO31	The inputs of P43 and P44 can be set to TTL input buffers and the outputs to N-channel open-drain outputs (EV _{DD} withstand voltage).	
P50	Type 1			INTP1/SDI00/RXD0/SDA00/TBIO0/(TAO)	Port 5	
F 30			Input port	/(TMIOC1)/(CRxD0)	A 6-bit input/output port that can be	
P51				INTP2/SDO00/TXD0/TBIO1/(TMIOD1)/(CT	specified as an input or output in bits.	
101				xD0)	The input port can be set by software	
P52		Input /		(INTP1)	using an internal pull-up resistor.	
P53		output		(INTP2)	The inputs of P50 and P55 can be set	
P54				(INTP3)	to TTL input buffers.	
P55				(INTP4)/(CLKBUZ1)/(SCLK00)	The outputs of the P50, P51, and P55 can be set to N-channel open-drain output (EV _{DD} withstand voltage).	
P60				SCLA0	Port 6	
P61			Input /	SDAA0	An 8-bit input/output port that can be	
P62	Type 2			SS00/SCLA1	specified as an input or output in bits.	
P63		Input /		SDAA1	The output of P60 to P63 is an N-	
P64				TI10/TO10/CTxD1	channel open-drain output (6V	
P65	Туре 1	output		TI11/TO11/CRxD1	withstand voltage).	
P66				TI12/TO12	The input ports of P64~P67 can be set	
P67				TI13/TO13	by software to use internal pull-up resistors.	
P70		Input / output		KR0/SCLK21/SCL21/(VCOUT1)	Port 7	
P71				KR1/SDI21/SDA21/(VCOUT0)	An 8-bit input /output port that can be	
P72				KR2/SDO21	specified as an input or output in bits.	
P73				KR3/SDO01	The input port can be set by software	
P74	1			KR4/INTP8/SDI01/SDA01	using an internal pull-up resistor.	

(2/2)



P75				KR5/INTP9/SCLK01/SCL01	The outputs of the P71 and P74 can be
P76				KR6/INTP10/(RxD2)	set to N-channel open-drain output
P77				KR7/INTP11/(TxD2)	(EV _{DD} withstand voltage).
P100		Input / output	Analog function	ANI16/TI14/TO14	Port 10 A 1-bit input/output port that can be specified as an input or output in bits. The input port can be set by software using an internal pull-up resistor.
P110				TI15/TO15	Port 11
P111		Input / output	Input port	TI16/TO16	2-bit input/output port, which can be specified as input or output in bits. The input port can be set by software using an internal pull-up resistor.
P120	Type 1	Input / output	Analog function	ANI14/VCOUT0	Port 12 1-bit input /output port and 4-bit input
P121				X1	dedicated port
P122				X2/EXCLK	Only P120 can specify inputs or
P123	Type 3	input	Input port	XT1	outputs. Only the input port of the P120
P124	Type 3	input		XT2/EXCLKS	can be set by software to use the internal pull-up resistor. The P120 can be set to an analog input.
P130	Type 4	output	Output port	_	Port 13 1-bit output dedicated port and 2-bit
P136				—	input/output port, P136 and P137 can be
P137		Input/ output	Input port	INTP0/SWCLK/(SDI00)/(RXD0)	specified as input or output in bits. The input port can be set by software using internal pull-up resistors.
P140				CLKBUZ0/INTP6	Port 14
P141				CLKBUZ1/INTP7	A 7-bit input/output port that can be
P142			Input port	SCLK30/SCL30	specified as an input or output in bits.
P143				SDI30/RxD3/SDA30	The input port can be set by software
P144				SDO30/TxD3	using an internal pull-up resistor.
P146		Input / output		ANI15	The inputs of the P142 and P143 can
P147	Type 1		Analog function	ANI12/VREF0	be set to TTL input buffering. The output of the P142, P143, P144 can be set to N-channel open-drain output (EV_{DD} withstand voltage). P146, P147 can be set to analog input.
P150				ANI17	Port 15
P151				ANI18	A 4-bit input/output port that can be
P152		Input /	Analog	ANI19	specified as an input or output in bits.
P153		output	function	ANI20	The input port can be set by software using an internal pull-up resistor. Can be set to analog input.



					An input pin dedicated to an external
DECETD	RESETB Type 5 input —	t		reset must be connected to V_{DD} directly	
RESEID			or via a resistor when no external reset		
			is used.		

Note:

- 1. Set each pin to digital or analog (can be set in bits) via port mode control register x (PMCx).
- 2. For a description of the multiplexing function, see "4.2 Port Multiplexing Function".
- 3. The functions in Table () above can be assigned by setting the peripheral I/O redirection registers.



4.2 Port Multiplexing Function

(1/2)

The feature name	Input/output	Function
ANIO ~ ANI20	Input	The analog input of the A/D converter
ANO0, ANO1	output	The output of the D/A converter
INTP0 ~ INTP11	Innet	External interrupt request input
	Input	Designation of effective edges: ascending edges, falling
VCIN0	Input	The analog voltage input for comparator 0
VCIN10, VCIN11, VCIN12,	loput	The analog voltage/reference input for comparator 1
VCIN13	Input	The analog voltage/reference input for comparator i
VREF0	Input	The reference input for comparator 0
VCOUT0, VCOUT1	output	Comparator output
PGA0IN, PGA1IN	Input	PGA input
PGA0GND, PGA1GND	Input	PGA reference input
KR0 ~ KR7	Input	The key interrupts the input
CLKBUZ0, CLKBUZ1	output	Clock output / buzzer output
RTC1HZ	output	Correction clock (1Hz) output for the real-time clock
	Input	A active-low system reset input must be connected to $V_{\mbox{\scriptsize DD}}$ directly or via a
RESETB		resistor when no external reset is used.
CRxD0, CRxD1	Input	Serial data input for CAN
CTxD0, CTxD1	output	Serial data output for CAN
RxD0 ~ RxD3	Input	Serial interface UART0, UART1, UART2 serial data input
TxD0 ~ TxD3	output	Serial interface UART0, UART1, UART2 serial data output
SCL00, SCL01, SCL10, SCL11,		Serial clock output for the serial interface IIC00, IIC01, IIC10, IIC11,
SCL20, SCL21, SCL30, SCL31	output	IIC20, IIC21, IIC30, IIC31
SDA00, SDA01, SDA10, SDA11,		Serial data input/output for serial interfaces IIC00, IIC01, IIC10, IIC11,
SDA20, SDA21, SDA10, SDA11, SDA20, SDA21, SDA30, SDA31	Input / output	IIC20, IIC21, IIC30, IIC31
SCLK00, SCLK01, SCLK10, SCLK11, SCLK20, SCLK21,	Input / output	Serial interface serial clock input/output for SSPI00, SSPI01, SSPI10,
SCLK30, SCLK31		SSPI11, SSPI20, SSPI21, SSPI30, SSPI31
SDI00, SDI01, SDI10, SDI11,		Serial data input for serial interfaces SSPI00, SSPI01, SSPI10, SSPI11,
SDI20, SDI21, SDI30, SDI31	Input	SSPI20, SSPI21, SSPI30, SSPI31



(2/2)

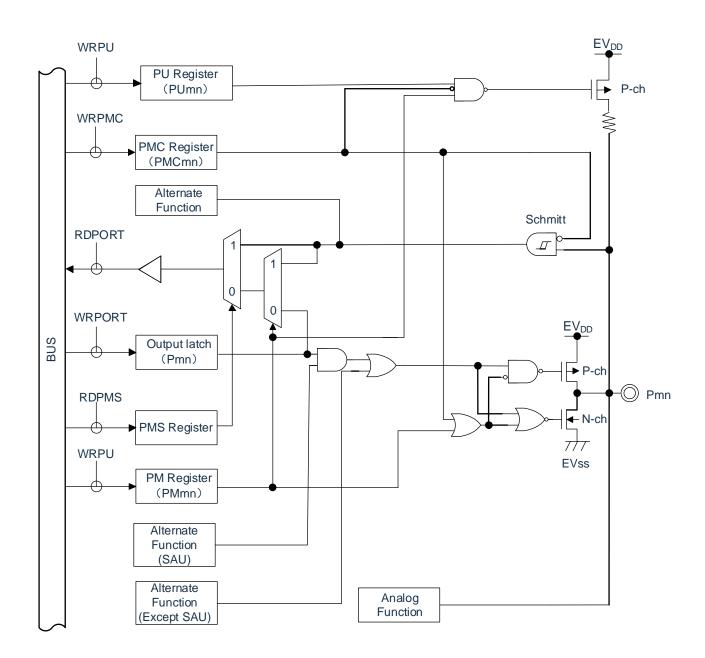
The feature name	Input/output	(2/2) Function
SS00	Input	Chip select input for serial interface SSPI00
SDO00, SDO01, SDO10, SDO11, SDO20, SDO21, SDO30, SDO31	output	Serial data output for SSPI00, SSPI01, SSPI10, SSPI11, SSPI20, SSPI21, SSPI30, SSPI31
SCLA0, SCLA1	Input/output	Serial interface IICA0, IICA1 clock input/output
SDAA0, SDAA1	Input/output	Serial interface IICA0, IICA1 serial data input/output
TUE00 ~ TI03	Input	External counting clock/capture trigger input for 16-bit timer Timer4
TO00 ~ TO03	output	Timer output of the 16-bit timer Timer4
TI10 ~ TI17	Input	External count clock/capture trigger input for 16-bit timer Timer8
TO10 ~ TO17	output	Timer output of the 16-bit timer Timer8
TAIO	Input/output	The input/output of timer TimerA
MAN	output	The output of timer TimerA
TMCLK	Input	Timer TimerM for the external clock input
TMIOA0, TMIOB0, TMIOC0,	Input/output	Timer TimerM input/output
TBIO0, TBIO1	Input/output	The input/output of timer TimerB
TBCLK0, TBCLK1	Input	The external clock input for timer TimerB
X1, X2	_	Connect the resonator used for the master system clock.
EXCLK	Input	The external clock input to the master system clock
XT1, XT2	_	Connect a resonator for the subsystem clock.
EXCLKS	Input	An external clock input to the secondary system clock
V _{DD}	_	<48Pin product>:Power supply for all pins <64,80Pin product>:
		Power supplies for P20 to P27, P121 to P124, P137, and RESETB pins
EV _{DD}	_	Power supplies for port pins (except P20 to P27, P121 to P124, P137, and RESETB).
AVREFP	Input	The positive (+) reference input of the A/D converter
AVREFM	Input	The negative (-) reference voltage input for the A/D converter
Vss <48Pin product>:Ground potential of all pins <64,80Pin product>: <64,80Pin product>: Ground potentials of the P20 to P27, P121 to P12		
EVss	The ground potential of the port pins (except P20 to P27, P121 to P137, and RESETB).	
SWDIO	Input/output	SWD data interface
SWCLK	Input	SWD clock interface

Note: As a countermeasure to noise and lockout, the bypass capacitor (around 0.1uF) must be connected at the shortest distance between V_{DD}-V_{SS} and EV_{DD}-EV_{SS} and with thicker wiring.



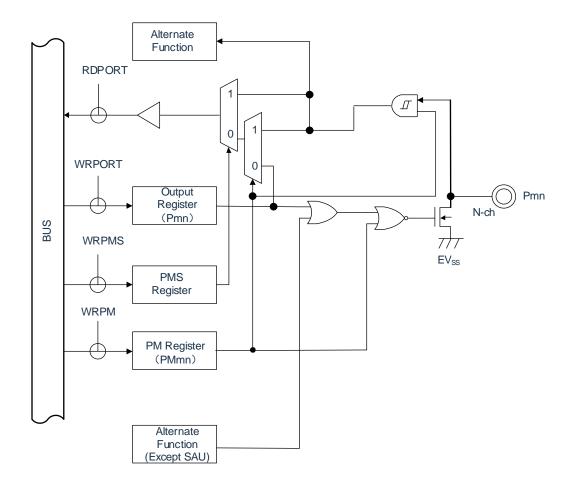
4.3 The Port Type

Type 1: Bidirectional I/O capability



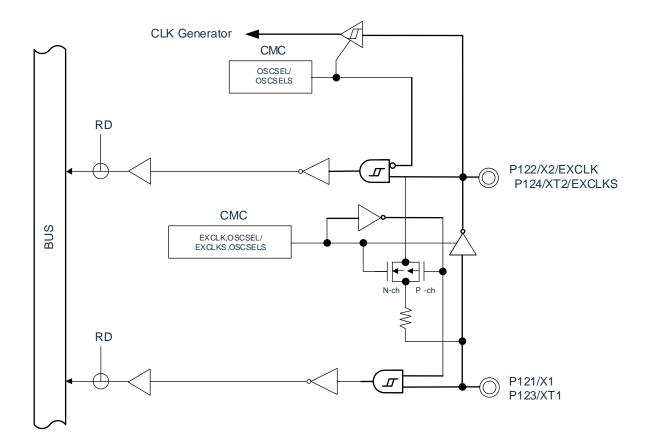


Type 2: NOD functionality





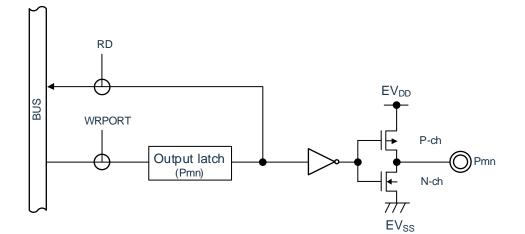
Type 3: Input function only



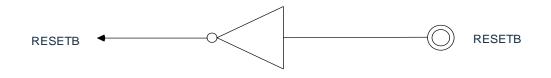




Type 4: Output function only



Type 5: RESET function





5 Feature Overview

5.1 ARM® Cortex-M0®+ Core

ARM's Cortex-M0+ processor is a new generation of ARM processors for embedded systems. It provides a low-cost platform designed to meet the needs of low pin count and low power microcontrollers while providing excellent computing performance and advanced system response to interrupts.

The Cortex-M0+ processor's 32-bit RISC processor provides superior code efficiency and provides the high performance expectations of the ARM core, unlike 8-bit and 16-bit devices of the same memory size. The Cortex-M0+ processor has 32 address lines and up to 4G of storage.

The Cortex-M0+ processor in this product integrates the MPU memory protection unit: providing a hardware way to manage and protect memory and control access rights.

The BAT32A239 uses an embedded ARM core and is therefore compatible with all ARM tools and software.

5.2 Memory

5.2.1 Flash Memory

The BAT32A239 has built-in flash memory that can be programmed, erased, and rewritten. It has the following functions:

- > Programs and data share 256K of storage.
- 2.5KB dedicated data flash memory
- Support page erase, each page size is 512byte
- Support byte/half-word/word (32bit) programming

5.2.2 SRAM

The BAT32A239 has a built-in 32K byte embedded SRAM.



5.3 Enhanced DMA Controller

The built-in enhanced DMA (Direct Memory Access) controller enables data transfer between memories without using a CPU.

- Supports start-up DMA via peripheral interrupts, enabling real-time control via communication, timers, and A/D.
- > The source/destination field is optional for the full address space range (when the flash field is the destination address, flash needs to be preset as the programming mode).
- Supports 4 transfer modes (normal transfer mode, repeat transfer mode, block transfer mode, and chain transfer mode).

5.4 Linkage Controller

The linkage controller links the events output by each peripheral function with the peripheral function trigger source. This enables collaborative operation between peripheral functions without using the CPU.

The UMC has the following functions:

- > It can link event signals together to achieve the linkage of peripheral functions.
- > There are 23 types of event inputs and 10 kinds of event triggers.



5.5 The Clock Generation and Start Up

A clock generation circuit is a circuit that generates a clock to the CPU and peripheral hardware. There are three types of system clock and clock oscillation circuitry.

5.5.1 The Master System Clock

- X1 oscillation circuit: It can generate a clock oscillation of 1 to 20MHz by connecting a resonator to the pins (X1 and X2), and can stop the oscillation by executing a deep sleep command or setting MSTOP.
- High Speed Internal Oscillator (High Speed OCO): Oscillates by selecting the frequency via option bytes. After the reset is released, the CPU starts operation by default with this high-speed internal oscillator clock. Oscillation can be stopped by executing a deep sleep command or setting the HIOSTOP bit. The frequency set by the option byte can be changed through the frequency selection register of the highspeed internal oscillator. The maximum frequency is 64Mhz and the accuracy is ± 1.0%.
- Input to the external clock by pin (X2): (1~20MHz) and can be invalidated by executing a deep sleep instruction or setting the MSTOP bit.

5.5.2 Auxiliary System Clock

- XT1 oscillation circuit: Generates a clock oscillation of 32.768kHz by connecting a 32.768kHz resonator to pins (XT1 and XT2) and can be set to XTSTOP The bit stops the oscillation.
- Input external clock by pin (XT2): 32.768kHz, and can set the input of the external clock to be invalid by setting the XTSTOP bit.

5.5.3 Low-speed Internal Oscillator Clock

- Low-speed internal oscillator (low-speed OCO): Produces 15kHz (typical) The clock oscillates. You cannot use a low-speed internal oscillator clock as a CPU clock. Only the following peripheral hardware can operate through a low-speed internal oscillator clock:
- Watchdog Timer (WWDT)
- Real-Time Clock (RTC)
- > 15-bit interval timer
- Timer TimerA

5.5.4 PLL Clock

PLL: Can be used as the system clock. The PLL can select an external clock from the source clock or an internal high-speed oscillator clock.



5.6 **Power Management**

5.6.1 Power Supply Mode

 V_{DD} : External power supply with a voltage range of 2.0 to 5.5V. EV_{DD}: External power supply with a voltage range of 2.0 to 5.5V. The voltage at the V_{DD} pin must be equal to the voltage at the EV_{DD} pin.

5.6.2 Power-on Reset

The power-on reset circuit (POL) has the following functions.

- An internal reset signal is generated when the power is turned on. If the supply voltage (V_{DD}) is greater than the sense voltage (V_{POL}), the reset is released. However, the reset state must be maintained by voltage detection circuitry or an external reset before the operating voltage range is reached.
- Drag the supply voltage (V_{DD}) and detection voltage (V_{PDR}) to compare, when V_{DD} < V_{PDR}, an internal reset signal is generated. However, when the power supply drops, it must be transferred before it is less than the operating voltage range Deep sleepmode, or reset state via voltage detection circuit or external reset. If you want to restart the operation, you must confirm that the supply voltage has returned to the operating voltage range.

5.6.3 Voltage Detection

The voltage detection circuit sets the operating mode and sense voltage (V_{LVDH} , V_{LVDL} , V_{LVD}) via option bytes. The voltage detection (LVD) circuit has the following functions:

- Comparing the supply voltage (V_{DD}) to the sense voltage (V_{LVDH}, V_{LVDL}, V_{LVD}) generates an internal reset or interrupt request signal.
- The sense voltage of the supply voltage (V_{LVDH}, V_{LVDL}, V_{LVD}) can be selected by option bytes to select the sense level.
- Runs in deep sleep mode.
- When the power supply rises, the reset state must be maintained by voltage detection circuitry or external reset before reaching the operating voltage range. When the supply drops, it must be transferred to deep sleep mode before it is less than the operating voltage range, or set to reset by voltage detection circuitry or an external reset.
- > The operating voltage range varies depending on the user option byte setting.

5.7 Low Power Mode

The BAT32A239 supports two low-power modes for the best compromise between low power consumption, short start-up times, and available wake-up sources:

- Sleep Mode: Enters sleep mode by executing sleep commands. Sleep mode is the mode that stops the CPU from running the clock. Each clock continues to oscillate if the high-speed system clock oscillation circuit, high-speed internal oscillator, or subsystem clock oscillation circuit is oscillating before setting sleep mode. Although this mode does not allow the operating current to drop to the level of deep sleep mode, it is an effective mode when you want to restart processing immediately with an interrupt request or if you want to do intermittent operation frequently.
- Deep Sleep Mode: Enter Deep Sleep Mode by executing the Deep Sleep command. Deep sleep mode is a mode that stops the oscillation of the high-speed system clock oscillation circuit and the high-speed internal oscillator and stops the entire system. It can greatly reduce the operating current of the chip. Because deep sleep mode can be lifted by interrupt requests, it can also be run intermittently. However, in the case of the X1 clock, because the wait time to ensure oscillation stability is required when the deep sleep mode is released, it is necessary to select the sleep mode if it is necessary to start processing immediately with an interrupt request.

In either mode, the registers, flags, and data memory all remain in the pre-standby mode setting, and also maintain the state of the output latches and output buffers of the input/output ports.

5.8 Reset Function

The following 7 methods generate a reset signal.

- 1) Input external reset via the RESETB pin.
- 2) Internal reset is generated by program runaway detection of the watchdog timer.
- 3) An internal reset is generated by comparing the supply voltage and the sense voltage of the power-on reset (POR) circuit.
- 4) An internal reset is generated by comparing the supply voltage and the sense voltage of the voltage detection circuit (LVD).
- 5) Internal reset due to RAM parity error.
- 6) Internal reset due to access to illegal memory.
- 7) Software reset

Internal reset is the same as external reset, and after the reset signal is generated, the program is executed from the addresses written in addresses 0000H and 0001H.



5.9 Interrupt Function

The Cortex-M0+ processor has a built-in Nested Vector Interrupt Controller (NVIC) that supports up to 32 interrupt request (IRQ) inputs, as well as one non-maskable interrupt (NMI) input, as well as multiple internal exceptions.

This product extends 32 maskable interrupt requests (IRQs) and 1 non-maskable interrupt (NMI) to support up to 96 maskable interrupt sources and one non-maskable interrupt source. The actual number of interrupt sources varies by product.

		48 pins	64 pins	80 pins
Interrupts can be	external	11	12	12
masked	internal	33	33	44

5.10 Real-time Clock (RTC).

The real-time clock (RTC) has the following functions.

- Counters with year, month, day, day, hour, minute, and second.
- Fixed cycle interrupt function (period: 0.5 seconds, 1 second, 1 minute, 1 hour, 1 day, 1 month).
- > Alarm interrupt function (alarm: week, hour, minute)
- > 1Hz pin output function
- Supports crossover of the secondary system clock or master system clock as the operating clock of the RTC
- > The real-time clock interrupt signal (INTRTC) can be used as a wake-up in deep sleep mode
- > Supports a wide range of clock correction functions

Year, month, day, hour, minute, and second counts can only be performed if the secondary system clock (32.768kHz) or the crossover of the primary system clock is selected as the operating clock of the RTC. When a low-speed internal oscillator clock (15kHz) is selected, only a fixed-cycle interrupt function can be used.

5.11 Watchdog Timer

1-channel WWDT, 17bit watchdog timer runs with option byte setting count. The watchdog timer operates with a low-speed internal oscillator clock (15kHz). A watchdog timer is used to detect a program that is out of control. When a program runaway is detected, an internal reset signal is generated.

The following situations are judged to be out of control of the program:

- > When the watchdog timer counter overflows
- > When performing a 1-bit operation instruction on the Allow Register (WDTE) of the watchdog timer
- > When writing data other than "ACH" to the WDTE register
- > When writing data to the WDTE register while the window is closed



5.12 SysTick Timer

This timer is dedicated to RTOS, but can also be used as a standard decrement counter.

It features a 24-bit decreasing counter with a self-loading capacity counter that generates a shieldable system interrupt when the self-loading capacity counter reaches 0.

5.13 Timer Timer4

This product contains timer unit Timer4 with four 16-bit timers. Each 16-bit timer is called a "channel" and can be used as a separate timer or as a combination of multiple channels for advanced timer functionality.

For details of each feature, please refer to the following table.

Independent channel operation function	Multi-channel linkage operation function
Interval timer	Single trigger pulse output
Square wave output	PWM output
External event counters	Multiple PWM outputs
Crossover	
 Measurement of input pulse intervals 	
• Measurement of the high/low level width of the	
input signal	
Latency counters	

5.13.1 Independent Channel Operation Function

The independent channel operation function is a function that can use any channel independently of other channel operating modes. The stand-alone channel operation function can be used as the following modes:

- 1) Interval Timer: Can be used as a reference timer for interrupting at fixed intervals (INTTMs).
- 2) Square Wave Output: Whenever an INTTM interrupt is generated, a flip is triggered to output a square wave of 50% duty cycle from the timer output pin (TO).
- 3) External Event Counter: Counts the effective edge of the input signal at the timer input pin (TI) and can be used as an event counter to generate an interrupt if a specified number of times are reached.
- 4) Divider function (Channel 0 of unit 0 only): The input clock of the timer input pin (TI00) is divided and then output from the output pin (TO00).
- 5) Measurement of input pulse interval: The interval between input pulses is measured by counting at the effective edge of the input pulse signal at the timer input pin (TI) and the effective edge of the next pulse is captured with the count value.
- 6) Measurement of the high/low width of the input signal: The width of the input signal is measured by counting at one edge of the input signal at the timer input pin (TI) and capturing the count value on the other edge.
- 7) Delay Counter: The active edge of the input signal at the timer input pin (TI) begins to count and generates an interrupt after any delay period has elapsed.



5.13.2 Multi-channel Linkage Operation Function

The multi-channel linkage operation function can combine the functions implemented by combining the master channel (the reference timer for the main control period) and the slave channel (the timer that operates in accordance with the main control channel). The multi-channel linkage operation function can be used as the following modes:

- 1) Single-trigger pulse output: Two channels are used in pairs to generate a single-trigger pulse that arbitrarily sets the output timing and pulse width.
- 2) PWM (Pulse Width Modulation) output: 2 channels are used in pairs to generate pulses that can arbitrarily set the period and duty cycle.
- 3) Multiple PWM (Pulse Width Modulation) output: Up to 3 can be generated in fixed periods by extending the PWM function and using 1 master channel and multiple slave channels PWM signal for any duty cycle.

5.13.3 8-bit Timer Operation Function

The 8-bit timer run function uses a 16-bit timer channel as a function for two 8-bit timer channels. (Only Channel 1 and Channel 3 can be used).

5.13.4 LIN-bus Support Functionality

The Timer4 unit can be used to check whether the received signal in LIN-bus communication is suitable for the LIN-bus communication format.

- Detection of wake-up signals: The low width is measured by counting the beginning of the falling edge of the input signal at the UART serial data input pin (RxD) and capturing the count value on the rising edge. If the width of the low level is greater than or equal to a fixed value, it is considered a wake-up signal.
- 2) Detection of the spacer field: After detecting a wake-up signal, the low level width is measured by counting from the falling edge of the input signal at the UART serial data input pin (RxD) and capturing the count value on the rising edge. If the low level width is greater than or equal to a fixed value, it is considered to be a spacer field.
- 3) Measurement of synchronous field pulse width: After detecting the interval field, measure the low and high width of the input signal of the UART serial data input pin (RxD). The baud rate is calculated based on the bit interval of the synchronous field measured in this way.



5.14 Timer Timer8

80-pin products add timer unit Timer8 with eight 16-bit timers. Each 16-bit timer is called a "channel" and can be used as a separate timer or as a combination of multiple channels for advanced timer functionality.

5.14.1 Independent Channel Operation Function

The independent channel operation function is a function that can use any channel independently of other channel operating modes. The stand-alone channel operation function can be used as the following modes:

- 1) Interval Timer: Can be used as a reference timer for interrupting at fixed intervals (INTTMs).
- 2) Square Wave Output: Whenever an INTTM interrupt is generated, a flip is triggered to output a square wave of 50% duty cycle from the timer output pin (TO).
- 3) External Event Counter: Counts the effective edge of the input signal at the timer input pin (TI) and can be used as an event counter to generate an interrupt if a specified number of times are reached.
- 4) Measurement of input pulse interval: The interval between input pulses is measured by counting at the effective edge of the input pulse signal at the timer input pin (TI) and the effective edge of the next pulse is captured with the count value.
- 5) Measurement of the high/low width of the input signal: The width of the input signal is measured by counting at one edge of the input signal at the timer input pin (TI) and capturing the count value on the other edge.
- 6) Delay Counter: The active edge of the input signal at the timer input pin (TI) begins to count and generates an interrupt after any delay period has elapsed.

5.14.2 Multi-channel Linkage Operation Function

The multi-channel linkage operation function can combine the functions implemented by combining the master channel (the reference timer for the main control period) and the slave channel (the timer that operates in accordance with the main control channel). The multi-channel linkage operation function can be used as the following modes:

- 1) Single-trigger pulse output: Two channels are used in pairs to generate a single-trigger pulse that arbitrarily sets the output timing and pulse width.
- 2) PWM (Pulse Width Modulation) output: 2 channels are used in pairs to generate pulses that can arbitrarily set the period and duty cycle.
- Multiple PWM (Pulse Width Modulation) output: Up to 7 can be generated in fixed periods by extending the PWM function and using 1 master channel and multiple slave channels PWM signal for any duty cycle.



5.14.3 8-bit Timer Operation Function

The 8-bit timer run function uses a 16-bit timer channel as a function for two 8-bit timer channels. (Only Channel 1 and Channel 3 can be used).

5.15 Timer TimerA

This product contains a 16bit timer TimerA consisting of a reload register and a decrement counter. Available for the following modes of operation:

- > Timer mode: Count the count source (the count source can be a clock or an external event)
- > Pulse output mode: Counts the counting source and outputs the pulse in case of overflow
- > Event Counting Mode: External events are counted and can work in deep sleep mode.
- > Pulse Width Measurement Mode: The external pulse width is measured
- > Pulse Period Measurement Mode: Measure the external pulse period

5.16 Timer Timer M

This product has a built-in 2-channel 16bit timer TimerM optimized for motor control, which has the following 4 operating modes:

- Timer mode:
 - Input capture function (triggered by an external signal to retrieve the count value to the register)
 - Output comparison function (detects whether the count value and register value are the same, and can change the output of the pin during the test)
 - PWM function (continuous output of arbitrary pulse width)
- Reset synchronous PWM mode: output sawtooth modulation, three-phase waveform without dead time (6 pcs)
- > Complementary PWM mode: output triangular modulation, three-phase waveform with dead time (6 pcs)
- > PWM3 Mode: Output Phase PWM Waveform (2 pcs)

5.17 Timer TimerB

This product has a built-in 16bit timer TimerB, which has the following 3 modes:

- Timer mode:
 - The input snap function counts on both sides of the rise, fall, or rise/fall edges.
 - Output comparison function "L" level output, "H" level output, or alternate output
- > PWM mode: PWM output capable of any duty cycle.
- > Phase counting mode: The count value of a 2-phase encoder can be measured automatically.



5.18 Timer TimerC

This product contains a 16 bit timer TimerC that can be triggered by software, comparator, or timer timerM for input capture.

5.19 15-bit Interval Timer

A built-in 15-bit interval timer generates interrupts (INTIT) at any pre-set interval that can be used to wake up from deep sleep mode.

5.20 Clock Output/Buzzer Output Control Circuitry

The clock output controller is used to provide the clock to the peripheral IC, and the buzzer output controller is used to output the square wave of the buzzer frequency. Clock output or buzzer output is implemented by a dedicated pin.



5.21 Universal Serial Communication Unit

This product has built-in 4 universal serial communication units, each unit has a maximum of 4 serial communication channels. Enables standard SPI, simple SPI, UART, and Simple I²C communication functions. Taking the 80pin product as an example, the function allocation of each channel is as follows:

5.21.1 3-Wire Serial Interface (Simple SPI)

The serial clock (SCK) output of the master device transmits and receives data synchronously.

This uses 1 serial clock (SCK), 1 transmit serial data (SO), and 1 receive serial data (SI) for a total of 3 A clock-synchronous communication interface for communication lines to communicate.

[Send and receive data].

- > 7-16 bits of data length
- > Phase control of sending and receiving data
- > MSB/LSB preferred choice

[Clock control].

- > The choice of master or slave
- > Phase control of the input/output clock
- > The transfer period generated by the prescaler and the in-channel counter
- Maximum transfer rate

Master communication: Max. Fclk/2

Slave communication: Max. $F_{\mbox{\scriptsize MCK}}/6$

[Interrupt function].

> End of transfer interrupt, buffer empty interrupt

[Error detection flag].

Overflow error



5.21.2 SPI with Slave Chip Select

SPI serial communication interface supporting slave chip select input. This uses a slave chip select input (SSI), a serial clock (SCK), a transmit serial data (SO), and a receive serial data (SI) together Clock-synchronous communication interface for communication of 4 communication lines.

[Send and receive data].

- > 7-16 bits of data length
- > Phase control of sending and receiving data
- > MSB/LSB preferred choice
- > Level settings for sending and receiving data

[Clock control].

- Phase control of the input/output clock
- > The transfer period generated by the prescaler and the in-channel counter
- Maximum transfer rate

Slave communication: Max. F_{MCK}/6

[Interrupt function].

> End of transfer interrupt, buffer empty interrupt

[Error detection flag].

Overflow error



5.21.3 UART

The function of asynchronous communication through two lines of serial data transmission (TxD) and serial data receiving (RxD). Using these two communication lines, data is sent and received asynchronously (using the internal baud rate) with other communicating parties in a data frame (consisting of a start bit, data, parity bit, and stop bit). Full-duplex UART communication can be achieved by using two channels, send private (even channel) and receive private (odd channel), and LIN-bus can be supported by combining Timer4 unit and external interrupt (INTP0).

[Send and receive data].

- > 7-bit, 8-bit, 9-bit, and 16-bit data length
- MSB/LSB preferred choice
- > Level setting and inversion selection of transmitted and received data
- > Additional parity functions for parity bits
- > Attaching of stop bits, detection of stop bits

[Interrupt function].

- > End of transfer interrupt, buffer empty interrupt
- > Error interrupts caused by frame errors, parity errors, or overflow errors

[Error detection flag].

> Frame error, parity error, overflow error

[LIN-bus function].

- Detection of wake-up signals
- Detection of spaced field (BF).
- > Measurement of the synchronous field, calculation of the baud rate



5.21.4 Simple I²C

The function of clock synchronization communication with multiple devices through two lines of serial clock (SCL) and serial data (SDA). Because this simple I²C is designed for single communication with devices such as flash memory and A/D converters, it can only be used as a master device. The start and stop conditions, like the operating control registers, must comply with the AC characteristics and be handled by software.

[Send and receive data].

- > Main control transmission, master receiving (limited to single main control master function)
- > ACK output function Note, ACK detection function

> 8 bits of data length (when sending the address, specify the address with a height of 7 bits, and use the lowest bit for R/W control).

> Start and stop conditions are generated through software

[Interrupt function].

> The end of the transfer is interrupted

[Error detection flag].

> ACK error, overflow error

[Features not supported by Simple I²C].

- Slave send, slave receive
- > Multi-master function (arbitration failure detection function)
- Wait for the detection function



5.22 Standard Serial Interface IICA

Serial interface IICA has the following 3 modes:

- Stop-Run mode: This is a mode used when no serial transfer is taking place, which reduces power consumption.
- I²C bus mode (multi-master supported): This mode transfers 8-bit data to multiple devices via two wires of the serial clock (SCLA) and the serial data bus (SDAA). In accordance with the I²C-bus format, the master device can generate "start conditions", "addresses", " for the slave devices on the serial data bus, "address", " Indication of the direction of transmission", "Data" and "Stop condition". The slave automatically detects the received status and data through the hardware. This feature simplifies the I²C-bus control portion of the application. Because the SCLA and SDAA pins of the serial interface IICA are used as open-drain outputs, the serial clock line and serial data bus require pull-up resistors.
- Wake-up mode: In deep sleep mode, deep sleep mode can be released by generating an interrupt request signal (INTIICA) when receiving the extension code or local station address of the autonomous control device. This is set via the IICA control register.

5.23 Controller CAN

Universal CAN controller interface function in accordance with the CAN protocol in accordance with the standard in ISO 11898.

- > Compliant with ISO 11898 and tested in accordance with ISO/DIS 16845 (CAN Conformity).
- > Use standard frames and extended frames to implement receive and send
- Communication speed: maximum 1Mbps. (CAN input clock greater than or equal to 8MHz)
- > 1 channel has 16 message caches
- Receive/send history list function
- Automatic block transfer function
- Multi-cache receive block capability
- > Masking settings for four modes per channel



5.24 Analog-to-digital Converters (ADCs).

This product contains a 12-bit resolution analog-to-digital converter SARADC, which converts analog inputs to digital values, and supports up to 21 channels of ADC analog inputs (ANI0 to ANI20). The ADC contains the following features:

- > 12-bit resolution, slew rate 1.42Msps.
- > Trigger mode: Support software trigger, hardware trigger and hardware trigger in standby
- > Channel selection: Supports two modes: single-channel selection and multi-channel scanning
- > Conversion mode: Supports single conversion and continuous conversion
- \succ Operating voltage: Supports 2.0V \leqslant V_{DD} \leqslant 5.5V operating voltage range
- Senses the built-in reference voltage (1.45V) and temperature sensor.

	Software triggered	Start the conversion with software operation.
	Hardware triggers no-wait	Start the conversion by detecting a hardware trigger.
Trigger mode	The hardware triggers the wait mode	In power-off transition standby, power is plugged in by detecting a hardware trigger and the transition automatically begins after the A/D power stabilization wait time.
Channel coloction	Select the mode	Select 1 channel of analog inputs for A/D conversion.
Channel selection mode	Scan mode	A/D conversion of analog inputs for 4 channels sequentially. Four consecutive channels from ANI0 to ANI15 can be selected as analog
	Single conversion mode	Performs 1 A/D conversion on the selected channel.
Conversion mode	Continuous conversion mode	Continuous A/D conversion of the selected channel until stopped by the software.
Sample time/conversion time	Number of sample clocks/conversion clocks	The sample time can be set by registers, with the default value of 13.5 clk for the number of sample clocks and 31.5 clk for the number of converted clocks.

5.25 Digital-to-analog Converters (DAC)

This product contains a 2-channel 8-bit resolution analog-to-digital converter DAC that converts digital inputs to analog signals. Has the following characteristics:

- > 8-bit resolution D/A converter
- > Supports the outputs of two independent analog channels
- R-2R ladder network
- Built-in real-time output function



5.26 Programmable Gain Amplifier (PGA)

Two programmable gain amplifiers (PGA0 and PGA1) are included in this product with the following functions

- > There are 7 options for amplification gain per PGA: 4x, 8x, 10x, 12x, 14x, 16x, 32x
- An external pin can be selected as ground for the PGA negative feedback resistor (available as differential mode).
- The output of PGA0 can be selected as an analog input for an A/D converter or as an analog input at the positive end of Comparator 0 (CMP0).
- > The output of PGA1 can be selected as an analog input for A/D converters

5.27 Comparators (CMP)

This product has built-in two-channel comparators CMP0 and CMP1 with the following functions:

- > External input and reference multi-channel options for CMP1.
- > An external reference input and an internal reference voltage can be selected for the reference.
- > The cancellation width of the noise cancellation digital filter can be selected.
- > Detects the active edge of the comparator output and generates an interrupt signal.
- > Detects the active edge of the comparator output and outputs the event signal to the linkage controller.

5.28 Two-wire Serial Debug Port (SW-DP)

ARM's SW-DP interface allows connection to a microcontroller via a serial line debugging tool.

5.29 Security Features

5.29.1 Flash CRC Computing Functions (High-speed CRC, Generalpurpose CRC)

Detect data errors in flash memory by CRC operation.

The following two CRCs can be used according to different uses and conditions of use.

> High-speed CRC: In the initialization program, it can stop the operation of the CPU and check the entire code flash memory area at high speed.

> Generic CRC: In CPU operation, it is not limited to the flash memory area of the code but can be used for multi-purpose inspection.

5.29.2 RAM Parity Error Detection Function

When reading RAM data, parity errors are detected.

5.29.3 SFR Protection Features

Prevent important SFRs (Special Function Registers) from being overwritten due to CPU runaways.

5.29.4 Illegal Memory Access Detection Function

Detects illegal access to illegal memory areas (areas without memory or areas with restricted access).

5.29.5 Frequency Detection Function

Self-test CPU or peripheral hardware clock frequency using Timer4 units.

5.29.6 A/D Testing Capabilities

The A/D is converted to the A/D converter's positive (+) reference, negative (-) reference, analog input channel (ANI), temperature sensor output voltage, and internal reference voltage. The converter performs self-test.

5.29.7 Digital Output Signal Level Detection Function for

Input/Output Ports

When the input/output ports are in output mode, the output level of the pin can be read.

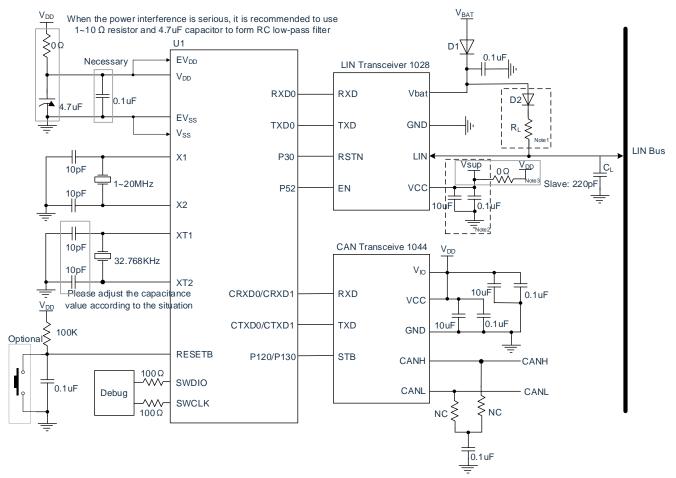
5.30 Key Function

A key interrupt (INTKR) can be generated by pressing the key interrupt input pin (KR0 to KR7) to enter the falling edge.



6 Electrical Characteristics

6.1 **Typical Application of Peripheral Circuits**



Device connections for typical MCU application peripheral circuits refer to the following:

- Note 1: D2 should be connected only when it is used as a host node, and a 660Ω/6.8nF RL/CL combination is recommended when the RL is used as a host node to obtain a slower slope of the bus waveform;
- Note 2: The LIN transceiver 1028 has an internal LDO that can provide a 5V power supply for the system through the VCC pin.
- Note 3: Vsup is the 5V power supply output from the 1028, while VDD is the system power supply.



6.2 Absolute Maximum Voltage Rating

(T_A= -40~125°C)

Item	Symbol	Condition	Rating	Unit	
Supply voltage	V _{DD}	-	-0.5~+6.5	V	
Supply voltage	EVDD	-	-0.5~+6.5	V	
		P00~P06, P10~P17, P30, P31, P40~P45			
	N	P50~P55, P64~P67, P70~P77, P100	-0.3~EV _{DD} +0.3 and	V	
	V _{I1}	P110~P111, P120, P136, P140~P144	-0.3~V _{DD} +0.3 ^{Note1}	V	
Input voltage		P146~P147			
	V _{I2}	P60~P63(N-channel drain open)	-0.3~+6.5	V	
		P20~P27, P121~P124, P137, P150~P153,			
	V _{I3}	EXCLK,EXCLKS, RESETB	-0.3~V _{DD} +0.3 ^{Note1}	V	
		P00~P06, P10~P17, P30, P31, P40~P45			
		P50~P55, P60~P67, P70~P77, P100 -0.3~EV _{DD} +0			
Output voltage	e V ₀₁	P110~P111, P120, P136, P140~P144	-0.3~V _{DD} +0.3 ^{Note1}	V	
		P146~P147			
	V _{O2}	P20~P27, P137, P150~P153	-0.3~V _{DD} +0.3 ^{Note1}	V	
			-0.3~EV _{DD} +0.3 and	N	
Analog input	Vai1	ANI8~ANI20	-0.3~AV _{REF} (+)+0.3 Note1,2	V	
voltage	Maria		-0.3~V _{DD} +0.3 and	V	
	V _{AI2}	ANIO~ANI7	-0.3~AV _{REF} (+)+0.3 Note1,2	v	

Note1: Not to exceed 6.5V.

Note2: The pin of the A/D conversion object cannot exceed $AV_{REF}(+)+0.3$.

Note: Even if 1 item in each project exceeds the absolute maximum rating instantaneously, the quality of the product may be reduced. The absolute maximum rating is the rating that may cause physical damage to the product and must be used in a state that does not exceed the rated value.

Remark:

- 1. Unless specifically specified, the characteristics of the multiplexed pin are the same as those of the port pin.
- 2. AV_{REF}(+): The positive (+) reference voltage of the A/D converter
- 3. Use V_{SS} as the reference voltage.
- 4. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



6.3 Absolute Maximum Current Rating

/ T	10 4	$ OE^{\circ} O \rangle$
	-40~	125°C)

Item	Symbol		Condition	Rating	Unit
		Each pin	P00~P06, P10~P17, P30, P31, P40~P45, P50~P55 P64~P67, P70~P77, P100, P110~P111, P120, P130 P136, P137, P140~P144, P146~P147	-40	mA
High output current	Іон1	Total pins -	P00~P04, P40~P45, P120, P130, P136, P137 P140~P144	-70	mA
ourion		170mA	P05, P06, P10~P17, P30, P31, P50~P55, P64~P67 P70~P77, P100, P110~P111, P146, P147	-100	mA
	laur	Each pin	D20 D27 D150 D152	-3	mA
	IOH2	Total pins	– P20~P27, P150~P153	-15	mA
Low output current		Each pin	P00~P06, P10~P17, P30, P31, P40~P45, P50~P55 P60~P67, P70~P77, P100, P110~P111, P120, P130 P136, P137, P140~P144, P146~P147	40	mA
	I _{OL1}	The total	P00~P04, P40~P45, P120, P130, P136, P137 P140~P144	100	mA
		pins are 170mA	P05, P06, P10~P17, P30, P31, P50~P55, P60~P67 P70~P77, P100, P110~P111, P146, P147	120	mA
		Each pin	D00 D07 D150 D150	15	mA
I _{OL2}		Total pins	otal pins P20~P27, P150~P153		mA
Input negative	l	Each pin	Continuous DC negative current that can be injected	-3	mA
current	Iinjl	Pin total	into an input pin	-15	mA
Input positive	Iinjh	Each pin	Continuous DC positive current that can be injected	3	mA
current	IINJH	Pin total	into an input pin	15	mA
Operating		Usually run			
ambient temperature	TA	When flash p	rogramming	-40~125	°C
Storage temperature	T _{stg}		-	-65~150	°C

Note: Even if 1 item in each project exceeds the absolute maximum rating instantaneously, the quality of the product may be reduced. The absolute maximum rating is the rating that may cause physical damage to the product and must be used in a state that does not exceed the rated value.

Remark:

- 1. Unless specifically specified, the characteristics of the multiplexed pin are the same as those of the port pin.
- 2. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



6.4 Oscillation Circuit Characteristics

6.4.1 X1, XT1 Features

ltem	Resonators	Condition	Min	Тур	Max	Unit
X1 clock oscillation frequency (F _x).	Ceramic resonator/crystal resonator	-	1.0	-	20.0	MHz
X1 clock oscillation settling time	Ceramic resonator/crystal resonator	20MHz,C=10pF	-	15	-	ms
X1 clock oscillation feedback resistor	Ceramic resonator/crystal resonator	-	0.6	-	1.8	MΩ
XT1 clock oscillation frequency (F _{XT}).	Crystal resonators	-	32	32.768	35	kHz
XT1 clock oscillation settling time	Crystal resonators	32.768kHz,C=20pF	-	2	-	s

 $(T_{A}=-40\sim125^{\circ}C, 2.0V \le V_{DD} \le 5.5V, V_{SS}=0V)$

Note:

1. It only indicates the frequency tolerance range of the oscillation circuit, and refer to the AC characteristics for the execution time of the instruction.

2. Please commission a resonator manufacturer to evaluate the installation circuit and use it after confirming the oscillation characteristics.

3. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



6.4.2 Internal Oscillator Features

(T _A = -40~125°C,2.0V≤V _{DD} ≤5.5V,V _{SS} =0V)
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Resonators	Condition	Min	Тур	Max	Unit
Clock frequency (F_{IH}) of the high-speed internal oscillator Note1,2	-	1.0	-	64.0	MHz
High-speed internal oscillator settling time (Tsu).	-	-	12	-	us
	T _A = 10~70°C	-1.0	-	+1.0	%
Clock frequency accuracy of a high-speed	T _A =0~105°C	-1.5	-	+1.5	%
internal oscillator	T _A = -10~125°C	-2.0	-	+2.0	%
	T _A = -40~125°C	-4.0	-	+4.0	%
The clock frequency (F _{IL}) of the low-speed internal oscillator	-	12	15	18	KHz

Note:

- 1. Select the frequency of the high-speed internal oscillator via the option byte.
- 2. Indicates only the characteristics of the oscillation circuit, please refer to the AC characteristics for the execution time of the instruction.
- Remark: Low temperature specification value shall be guaranteed by the design, and low temperature conditions shall not be measured in mass production.

6.4.3 PLL Oscillator Characteristics

(T _A = -40~125°C,2.0V≤V _{DD} ≤5.5V,V _{SS} =	=0V)
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Resonators	Condition	Min	Тур	Max	Unit
PLL input frequency Note1	-	4.0	-	8.0	MHz
PLL lock time	-	40	-	-	ms

Note1: Only the characteristics of the oscillation circuit are indicated, please refer to the AC characteristics for the execution time of the instruction

Remark: Low temperature specification value shall be guaranteed by the design, and low temperature conditions shall not be measured in mass production.



6.5 DC Characteristics

6.5.1 Pin Characteristics

(T _A = -40~125°C,2.0V≤EV _{DD} =V _{DD} ≤5.5V,V _{SS} =E _{VSS} =0V)

Project	Symbol	Condition		Min	Тур	Max	Unit
		P00~P06, P10~P17, P30, P31 P40~P45, P50~P55, P64~P67 P70~P77, P100, P110~P111	2.0V≪EV _{DD} ≪5.5V -40~85°C	-	-	-12.0 ^{Note2}	
		P120, P130, P136, P137 P140~P144, P146~P147 1 pin alone	2.0V≪EV _{DD} ≪5.5V 85~125°C	-	-	-6.0 ^{Note2}	. mA
		P00~P04, P40~P45, P120	4.0V≤EV _{DD} ≤5.5V -40~85°C	-	-	-60.0	m (
		P130, P136, P137 P140~P144 Total pins	4.0V≤EV _{DD} ≤5.5V 85~125°C	-	-	-30.0	mA
		(at duty cycle \leq 70% ^{Note3})	2.4V≤EV _{DD} <4.0V	-	-	-12.0	mA
	Іон1		2.0V≤EV _{DD} <2.4V	-	-	-6.0	mA
		P05, P06, P10~P17, P30, P31 P50~P55, P64~P67, P70~P77 P100, P110~P111 P146, P147Total pins (at duty cycle \leq 70% ^{Note3}).	4.0V≤EV _{DD} ≤5.5V -40~85°C	-	-	-80.0	
High output current Note1			4.0V≤EV _{DD} ≤5.5V 85~125°C	-	-	-30.0	mA
			$2.4V \leq EV_{DD} \leq 4.0V$	-	-	-20.0	mA
			$2.0V \leq EV_{DD} < 2.4V$	-	-	-10.0	mA
		Total pins (at duty cycle ≤ 70% ^{Note3})	4.0V≤EV _{DD} ≤5.5V -40~85°C	-	-	-140.0	
			4.0V≤EV _{DD} ≤5.5V 85~125°C	-	-	-60.0	mA
			2.4V≤EV _{DD} ≤4.0V	-	-	-30.0	
			2.0V≤EV _{DD} ≤2.4V	-	-	-15.0	
	Іон2	P20~P27,P150~P153 1 pin alone	2.0V≤V _{DD} ≤5.5V	-	-	-2.5 Note2	mA
		Total pins (at duty cycle \leq 70% ^{Note3})	$2.0V \leq V_{DD} \leq 5.5V$	-	-	-10	mA

Note1: This is the current value that guarantees the operation of the device even if the current flows from the EV_{DD} and V_{DD} pins to the output pins.

Note2: The total current value cannot be exceeded.

Note3: This is the output current value for the "duty cycle ≤70% condition". The output current value > of 70% can be calculated using the following calculation method (if the duty cycle is changed to n%). Total output current of pins = (I_{OH}×0.7)/(n×0.01). <calculation example>I_{OH} = -10.0mA,n =80%

Total output current of pins = (-10.0×0.7)/(80×0.01) ≈-8.7mA

The current at each pin does not vary due to duty cycle and does not flow above the absolute maximum rating.

Note: In N-channelopen-drain mode, pins set to active N-channel open-drain do not output high.

Remarks:

- 1. Unless specifically specified, the characteristics of the multiplexed pin are the same as those of the port pin.
- 2. Low temperature specification value shall be guaranteed by the design, and low temperature conditions shall not be measured in mass production.



Project	Symbol	Condition		Min	Тур	Max	Unit
		P00~P06, P10~P17, P30, P31 P40~P45, P50~P55, P60~P67 P70~P77, P100, P110~P111, P120	2.0V≤EV _{DD} ≤5.5V -40~85°C	-	-	30 Note2	mA
		P130, P136, P137, P140~P144 P146~P147 1 pin alone	2.0V≪EV _{DD} ≪5.5V 85~125°C	-	-	15 Note2	
			4.0V≤EV _{DD} ≤5.5V -40~85°C	-	-	100	
		P00~P04, P40~P45, P120, P130 P136, P137, P140~P144 Total pins (at duty cycle ≤ 70% ^{Note3})	4.0V≪EV _{DD} ≪5.5V 85~125°C	-	-	50	mA
		Total pins (at duty cycle ≤ 70% ^{Note3}).	2.4V≤EV _{DD} <4.0V	-	-	30	mA
Low			2.0V≤EV _{DD} <2.4V	-	-	15	mA
output	IOL1	.1 P05, P06, P10~P17, P30, P31 P50~P55, P60~P67, P70~P77, P100 P110~P111, P146, P147 Total pins (at duty cycle ≤ 70% ^{Note3}).	4.0V≪EV _{DD} ≪5.5V -40~85°C	-	-	120	
Note1			4.0V≪EV _{DD} ≪5.5V 85~125°C	-	-	60	mA
			2.4V≤EV _{DD} <4.0V	-	-	40	mA
			2.0V≤EV _{DD} <2.4V	-	-	20	mA
			4.0V≪EV _{DD} ≪5.5V -40~85°C	-	-	150	
		Total pins (at duty cycle ≤ 70% ^{Note3})	4.0V≤EV _{DD} ≤5.5V 85~125°C	-	-	80	mA
			2.4V≤EV _{DD} ≤4.0V	-	-	50	
			2.0V≤EV _{DD} ≤2.4V	-	-	30	
	lava	P20~P27, P150~P153 1 pin alone	2.0V≤V _{DD} ≤5.5V	-	-	6 Note2	mA
	IOL2	Total pins (at duty cycle ≤ 70% ^{Note3})	$2.0V \leq V_{DD} \leq 5.5V$	-	-	20	mA

(T_A= -40~125°C, 2.0V≤EV_{DD}=V_{DD}≤5.5V, V_{SS}=EV_{SS}=0V)

Note1: This is the current value that guarantees the operation of the device even if the current flows from the output pin to the EVss and Vss pins.

- Note2: The total current value cannot be exceeded.
- Note3: This is the output current value for the "duty cycle ≤70% condition". The output current value of 70% is changed to duty cycle>can be calculated using the following calculation (if the duty cycle is changed to n%).

Total output current = $(I_{OL} \times 0.7)/(n \times 0.01)$.

<calculation example>I_{OL}= 10.0mA,n = 80%

Total Output Current = $(10.0 \times 0.7)/(80 \times 0.01) \approx 8.7$ mA Each pin does not vary due to duty cycle and does not flow above the absolute maximum rating.

Note:

- 1. Unless specifically specified, the characteristics of the multiplexed pin are the same as those of the port pin.
- 2. Low temperature specification value shall be guaranteed by the design, and low temperature conditions shall not be measured in mass production.



(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

Project	Symbol	Condition	,	Min	Тур	Max	Unit
Power supply input voltage	V _{DD} EV _{DD}	-		2.0	-	5.5	V
The supply ground input voltage	Vss EVss	-		-0.3	-	-	V
High input voltage	ViH1	P00~P06, P10~P17, P30, P31 P40~P45, P50~P55, P64~P67 P70~P77, P100, P110~P111 P120, P136, P140~P144 P146~P147	Schmidt input	0.8EV _{DD}	-	EVDD	V
		P01, P03, P04, P10, P14~P17	TTL input 4.0V≤EV _{DD} ≤5.5V	2.2	-	EV _{DD}	V
	VIH2	P30, P43~P44, P50, P55 P142~P143	TTL input 3.3V≤EV _{DD} <4.0V	2.0	-	EV _{DD}	V
		P142~P143	TTL input 2.0V≤EV _{DD} <3.3V	1.5	-	EV _{DD}	V
	V _{IH3}	P20~P27, P137, P150~P153	·	$0.7V_{DD}$	-	V _{DD}	V
	VIH4	P60~P63	0.7EV _{DD}	-	6.0	V	
	VIH5	P121~P124, EXCLK, EXCLKS, F	0.8V _{DD}	-	V _{DD}	V	
	VIL1	P00~P06, P10~P17, P30, P31 P40~P45, P50~P55, P64~P67 P70~P77, P100, P110~P111 P120, P136, P140~P144 P146~P147	Schmidt input	0	-	0.2EV _{DD}	V
Low input			TTL input 4.0V≪EV _{DD} ≪5.5V	0	-	0.8	V
voltage	VIL2	P01, P03, P04, P10, P14~P17 P30, P43~P44, P50, P55	TTL input 3.3V≪EV _{DD} <4.0V	0	-	0.5	V
		P142~P143	TTL input 2.0V≤EV _{DD} <3.3V	0	-	0.32	V
	VIL3	P20~P27, P137, P150~P153		0	-	0.3V _{DD}	V
	VIL4	P60~P63		0	-	0.3EV _{DD}	V
	VIL5	P121~P124, EXCLK, EXCLKS, F	RESETB	0	-	$0.2V_{\text{DD}}$	V

Note: Even N-channel open-drain mode, the V_{IH} maximum (MAX.) of the pin set to active N-channel opendrain is EV_{DD}.

Remark:

- 1. Unless specifically specified, the characteristics of the multiplexed pin are the same as those of the port pin.
- 2. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



Project	Symbol	EVDD=VDD≈5.5V, Vss=EVss= Conditio		Min	Тур	Max	Unit
			4.0V≤EV _{DD} ≤5.5V,	EV _{DD} -1.5	-	-	V
		P00~P06, P10~P17, P30	I _{OH1} = -12.0mA				
		P31, P40~P45, P50~P55	4.0V≤EV _{DD} ≤5.5V,	EV _{DD} -0.7	-	-	V
	V _{OH1}	P64~P67, P70~P77, P100	$I_{OH1} = -6.0 \text{mA}$				
		P110~P111, P120, P130	2.4V≤EV _{DD} ≤5.5V,	EV _{DD} -0.6	-	-	V
		P136, P137, P140~P144 P146~P147	loн1= -3.0mA				
		P 140~P 147	2.0V≤EV _{DD} ≤5.5V,	EV _{DD} -0.5	-	-	V
High output voltage			I _{OH1} = -2mA				
			4.0V≤V _{DD} ≤5.5V,	EV _{DD} -1.5	-	-	V
			I _{OH2} = -2.5mA				
	V _{OH2}		4.0V≤V _{DD} ≤5.5V,	EV _{DD} -0.7	-	-	V
		P20~P27, P150~P153	I _{OH2} = -1.5mA				
			2.4V≤V _{DD} ≤5.5V,	EV _{DD} -0.6	-	-	V
			I _{OH2} = -0.5mA				
			2.0V≤V _{DD} ≤5.5V,	V _{DD} -0.5	-	-	V
			I _{OH2} = -0.4mA				
			4.0V≤EV _{DD} ≤5.5V,	-	-	1.2	V
		P00~P06, P10~P17, P30	I _{OL1} =30.0mA				
		P31, P40~P45, P50~P55	4.0V≪EV _{DD} ≪5.5V,	-	-	0.7	V
	Vol1	P60~P67, P70~P77, P100	I _{OL1} =15.0mA				
		P110~P111, P120, P130	2.4V≤EV _{DD} ≤5.5V,	-	-	0.4	V
		P136, P137, P140~P144	I _{OL1} =6.0mA				
		P146~P147	2.0V≤EV _{DD} ≤5.5V,	-	-	0.4	V
Low output voltage			I _{OL1} =4.0mA				
			4.0V≪V _{DD} ≪5.5V,	-	-	1.2	V
			I _{OL2} =6.0mA				
			4.0V≪V _{DD} ≪5.5V,	-	-	0.7	V
	Vol2	P20~P27, P150~P153	I _{OL2} =4.0mA				
	V UL2	,	2.4V≤V _{DD} ≤5.5V,	-	-	0.4	V
			I _{OL2} =1.5mA		<u> </u>	0.4	
			2.0V≪V _{DD} ≪5.5V,	-	-	0.4	V
			I _{OL2} =1.0mA				

(T_A= -40 ~125°C, 2.0V≤EV_{DD}=V_{DD}≤5.5V, V_{SS}=EV_{SS}=0V)

Note: Even N-channel open-drain mode, pins set to active N-channel open-drain do not output high. Remark:

- 1. Unless specifically specified, the characteristics of the multiplexed pin are the same as those of the port pin.
- 2. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



Project	Symbol	Condition	,	Min	Тур	Max	Unit
High	ILIH1	P00~P06, P10~P17, P30, P31 P40~P45, P50~P55, P60~P67 P70~P77, P100, P110~P111 P120, P130, P136 P140~P144, P146~P147	V _I =EV _{DD}	-	-	1	uA
input leakage	I _{LIH2}	P20~P27, P137,P150~P153, RESETB	V _I =V _{DD}	-	-	1	uA
current	Іцнз	P121~P124(X1, X2, EXCLK XT1, XT2, EXCLKS)	V _I =V _{DD} , when the input port and external clock are in V _I =V _{DD} , when a	-	-	1	uA
			resonator is connected	-	-	10	uA
	ILIL1	P00~P06, P10~P17, P30, P31 P40~P45, P50~P55, P60~P67 P70~P77, P100, P110~P111 P120, P130, P136 P140~P144, P146~P147	V _I =EV _{SS}	-	-	-1	uA
Low input leakage	I _{LIL2}	P20~P27, P137,P150~P153, RESETB	V _I =V _{SS}	-	-	-1	uA
current	ILIL3	P121~P124(X1, X2, EXCLK	VI=VSS, when the input port and external clock are in	-	-	-1	uA
		XT1, XT2, EXCLKS)	V _I =V _{SS} , when a resonator is connected	-	-	-10	uA
Internal pull-up resistor	Ru	P00~P06, P10~P17, P30, P31 P40~P45, P50~P55, P64~P67 P70~P77, P100, P110~P111 P120, P136, P137 P140~P144, P146~P147	VI=EVss,when entering the port	10	30	100	ΚΩ

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

Note:

- 1. Unless specifically specified, the characteristics of the multiplexed pin are the same as those of the port pin.
- 2. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



6.5.2 Supply Current Characteristics

Project	Symbol		00– 000≪0.50, 0 Cc	ondition		Min	Тур	Max	Unit
			High-speed	F _{HOCO} =64MHz,F _{IH} =	64MHz ^{Note3}	-	7.6	15	
			internal	F _{HOCO} =48MHz,F _{IH} =	48MHz ^{Note3}	-	7.0	12	mA
			oscillator	FHOCO=32MHz,FIH=	32MHz Note3	-	6.0	10	
					Input square wave	-	4.0	8.0	
	IDD1	Run mode	High-speed master system	F _{MX} =20MHz ^{Note2}	Connecting crystal oscillator	-	4.0	8.0	mA
			The secondary	F _{SUB} =32.768КНz	Input square wave	-	70	150	
			system clock runs	Note4	Connecting crystal oscillator	-	70	150	uA
Cumple		Sleep mode	High-speed	FHOCO=64MHz,FIH=	64MHz Note3	-	2.0	7.8	
Supply current			internal oscillator	FHOCO=48MHz,FIH=	48MHz ^{Note3}	-	1.6	6.5	mA
Note1				Fносо=32MHz,Fiн=	32MHz ^{Note3}	-	1.2	4.5	
			High-speed master system	F _{MX} =20MHz ^{Note2}	Input square wave	-	0.7	3.2	
	I _{DD2}				Connecting crystal oscillator	-	0.7	3.2	mA
			The secondary	E	Input square wave	-	1.2	60	
			system clock runs	FSUB=32.768KHz Note5	Connecting crystal oscillator	-	1.2	60	uA
			T _A = -40°C~25°C	V _{DD} =3.0V		-	0.8	1.4	
	DD3 Note6	Deep sleep	T _A = -40°C~85°C	V _{DD} =3.0V		-	0.8	15	
	IDD3 Hoteo	mode ^{Note7}	T _A = -40°C~105°C V _{DD} =3.0V			-	0.8	22	uA
			T _A = -40°C~125°C	C V _{DD} =3.0V		-	0.8	55	

(T_A= -40~125°C, 2.0V≤EV_{DD}=V_{DD}≤5.5V, V_{SS}=EV_{SS}=0V)

Note2: This is a case where the high-speed internal oscillator and the subsystem clock stop oscillating.

Note3: This is when the high-speed master system clock and the secondary system clock stop oscillating.

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Note1: This is the total current flowing through V_{DD} and EV_{DD}, including input pins fixed as V_{DD}, EV_{DD} or V_{SS}, EV_{SS} The input leakage current of the state. TYP. Value: The CPU is in multiplication instruction execution (I_{DD1}) and does not contain peripheral operating current. MAX.Value: The CPU is in multiplication instruction execution (I_{DD1}) and contains peripheral operating current, but does not contain current flowing to the A/D converter, LVD circuitry, I/O port, and internal pull-up or pull-down resistors. It also does not include the current at which the data flash is overwritten.

- Note4: This is a case where the high-speed internal oscillator and the high-speed master system clock stop oscillating.
- Note5: This is a case where the high-speed internal oscillator and the high-speed master system clock stop oscillating. Contains current flowing to the RTC, but does not flow to the 15-bit interval timer and watchdog The current of the timer.

Note6: Does not include current to RTCs, 15-bit interval timers, and watchdog timers.

Note7: For current values when the secondary system clock is running in deep sleep mode, refer to the current value when the secondary system clock is running in sleep mode.

Remark:

- FHOCO: Clock frequency of high-speed internal oscillator,
 FIH: System clock frequency provided by high-speed internal oscillator.
- 2. F_{SUB}: External subsystem clock frequency (XT1/XT2 clock oscillation frequency).
- 3. F_{MX}: External master system clock frequency (X1/X2 clock oscillation frequency).
- 4. TYP. The temperature condition of the value is $T_A=25^{\circ}C$.
- 5. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



(TA= -40~ T25 C, 2.0V < E V DD= V DD < 5.5V, V SS=E V SS=0V)							
Parameter	Symbol		Condition	Min	Тур	Max	Unit
Low-speed internal oscillator operating current	I _{FIL} Note1		-	-	0.2	-	uA
RTC operating current	I _{RTC} ^{Note1,2,3}		-	-	0.04	-	uA
15-bit interval timer operating current	IT Note1,2,4		-	-	0.02	-	uA
Watchdog timer operating current	WDT Note1,2,5	F⊫=15KHz	-	0.22	-	uA	
		ADC HS mo	DC HS mode@64MHz		2.2	-	mA
The A/D converter	ADC Note 1,6	ADC HS mo	-	1.3	-	mA	
operates current	IADC	ADC LC mode@24MHz		-	1.1	-	mA
		ADC LC mode@4MHz		-	0.8	-	mA
The D/A converter operates current	DAC Note1,8	Per channel		-	1.4	-	mA
PGA operating current	-	Per channel		-	480	700	uA
Comparator operating	ICMP Note1,9	Por chonnel	The internal reference voltage is not used	-	60	100	uA
current	ICMP Note 1,9	Per channel	An internal reference voltage is used	-	80	140	uA
LVD operating current	LVD Note1,7		-	-	0.08	-	uA

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

Note1: This is the current flowing through V_{DD}.

- Note2: This is a case where the high-speed internal oscillator and the high-speed system clock stop oscillating.
- Note3: This is the current that only flows to the real-time clock (RTC) (excluding the operating current of the low-speed internal oscillator and XT1 oscillation circuitry). With the real-time clock running in operating mode or sleep mode, the current value of the microcontroller is I_{DD1} or I_{DD2} plus the value of I_{RTC}. In addition, when selecting a low-speed internal oscillator, I_{FIL} must be added. I_{DD2} when the subsystem clock is running contains the operating current of the real-time clock.
- Note4: This is the current that only flows to the 15-bit interval timer (excluding the operating current of the low-speed internal oscillator and the XT1 oscillation circuit). In the case of a 15-bit interval timer in operating mode or sleep mode, the current value of the microcontroller is I_{DD1} or I_{DD2} plus the value of I_{IT}. In addition, when selecting a low-speed internal oscillator, IFIL must be added.
- Note5: This is the current that only flows to the watchdog timer (including the operating current of the lowspeed internal oscillator). With the watchdog timer running, the current value of the microcontroller is I_{DD1} or I_{DD2} or I_{DD3} plus the value of I_{WDT}.
- Note6: This is the current that only flows to the A/D converter. In either run mode or sleep mode with the A/D converter running, the current value of the microcontroller is I_{DD1} or I_{DD2} plus the value of I_{ADC}.
- Note7: This is the current that only flows to the LVD circuit. In the case of LVD circuit operation, the current value of the microcontroller is I_{DD1} or I_{DD2} or I_{DD3} plus the value of I_{LVD} .
- Note8: This is the current that only flows to the D/A converter. When the D/A converter is running in operating

or sleep mode, the current value of the microcontroller is I_{DD1} or I_{DD2} plus the value of I_{DAC} .

Note9: This is the current that only flows to the comparator circuit. With the comparator circuit running, the current value of the microcontroller is I_{DD1} or I_{DD2} or I_{DD3} plus the value of the I_{CMP}.

Remark:

- 1. F_{IL} : The clock frequency of the low-speed internal oscillator
- 2. TYP. The temperature condition of the value is $T_A = 25^{\circ}C$.
- 3. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



6.6 AC Characteristics

Item	Symbol		Conditi	on	Min	Тур	Max	Unit
Instruction period (minimum	Тсү	The master clock (FMAIN		2.0V≤V _{DD} ≤5.5V	0.015625	-	1	us
instruction execution time)	T CY	The secondary system clock (F _{SUB}) runs		2.0V≤V _{DD} ≤5.5V	28.5	30.5	31.3	us
External system	F _{EX}	2.0V≤V _{DD} ≤	2.0V≤V _{DD} ≤5.5V			-	20.0	MHz
clock frequency	F _{EXS}	2.0V≤V _{DD} ≤	2.0V≤V _{DD} ≤5.5V			-	35.0	KHz
The high or low	Texh,Texl	2.0V≤V _{DD} ≤5.5V			24	-	-	ns
level width of the external system clock input	Texhs, Texls	2.0V≤V _{DD} ≤	2.0V≤V _{DD} ≤5.5V			-	-	us
TI00 ~ TI03, TI10 ~ TI17 input high and low level width	Ттін,Тті∟	2.0V≪V _{DD} ≤	≦5.5V		1/Fмск+10	-	-	ns
The input period of	Ŧ	TAIO	2.4V≤EV	dd≪5.5V	100	-	-	ns
timer TimerA	Tc	TAIO	2.0V≤EV	_{DD} <2.4V	300	-	-	ns
The high or low		TAIO	2.4V≤EV _{DD} ≤5.5V		40	-	-	ns
level width of the timer TimerA input	Ttaih,Ttail	TAIO	2.0V≤EV	_{DD} <2.4V	120	-	-	ns

Note:

1. FMCK: Timer4, Timer8 unit running clock frequency

2. The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



$(T_{A}=-40\sim125^{\circ}C, 2.0V \le EV_{DD}=V_{DD} \le 5.5V, V_{SS}=EV_{SS}=0V)$

Project	Symbol		Condition	Min	Тур	Max	Unit
The high or low level width of the M input of the timer	Ttmih,Ttmil		TMIOA0, TMIOA1, TMIOB0, TMIOB1 TMIOC0, TMIOC1, TMIOD0, TMIOD1			-	ns
Timer M forces the cutoff			2MHz <f<sub>CLK≤48MHz</f<sub>	1	-	-	μs
of the low width of the signal input	T _{TMSIL}	P136/INTP0	$F_{CLK} \leqslant 2 MHz$	1/F _{CLK} +1	-	-	μs
The high and low level width of the timer B input	T _{TBIH} , T _{TBIL}	TBIOA,TBIOB		2.5/F _{CLK}	-	-	ns
TO00 ~ TO03, TO10 ~ TO17, TAIO0, TAO0, TMIOA0,		4.0V≤EV _{DD} ≤	5.5V	-	-	16	MHz
TMIOA1, TMIOB0, TMIOB1, TMIOC0, TMIOC1, TMIOD0,	Fто	2.4V≤EV _{DD} <4	2.4V≤EV _{DD} <4.0V		-	8	MHz
TMIOD1, TBIOB output frequency		2.0V≤EV _{DD} <2.4V		-	-	4	MHz
Output frequencies of		4.0V≤EV _{DD} ≤5.5V		-	-	16	MHz
CLKBUZ0 and CLK	F _{PCL}	2.4V≤EV _{DD} <4	2.4V≤EV _{DD} <4.0V		-	8	MHz
BUZ1		2.0V ≤ EV _{DD} < 2	2.4V	-	-	4	MHz
The high and low level width of the interrupt input	T _{INTH} , T _{INTL}	INTP0 ~ INTP11	2.0V≤EV _{DD} ≤5.5V	1	-	-	μs
The key interrupts the high or low level width of the input	Tĸĸ	KR0 ~ KR7	2.0V≤EV _{DD} ≤5.5V	250	-	-	ns
The low level width of RESETB	T _{RSL}		-	10	-	-	μs

Note: The low temperature specification value is guaranteed by the design, and the low temperature condition is not measured in mass production.



6.7 Peripheral Features

6.7.1 Universal Interface Unit

1) UART mode

(T_A= -40~85°C, 2.0V≤EV_{DD}=V_{DD}≤5.5V, V_{SS}=EV_{SS}=0V)

Item		Condition	Specifica	Unit	
nem		Condition	Min	Max	Unit
Transfor		-	-	Fмск/6	6 bps
Transfer rate	$2.0V \leq EV_{DD} \leq 5.5V$	The theoretical value of the maximum transfer rate is $F_{MCK}=F_{CLK}$	-	10.6	Mbps

$(T_{A}=85\sim125^{\circ}C, 2.0V \leq EV_{DD}=V_{DD} \leq 5.5V, V_{SS}=EV_{SS}=0V)$

Item		Condition	Specifica	Unit	
		Condition	Min	Max	Onit
Transfor		-	-	F _{мск} /12	bps
Transfer rate	$2.0V \leq EV_{DD} \leq 5.5V$	The theoretical value of the maximum transfer rate is $F_{\text{MCK}}{=}F_{\text{CLK}}$	-	5.3	Mbps

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(T _A =	-40~125°C,	2.0V≤EV _D	D=VDD≤ 5.5V,Vss=EV	ss=0V)				
ltom	Symbol	Condition		-40~85	°C	85~12	5°C	Linit
Item	Symbol		Condition	Min	Max	Min	Max	Unit
			$4.0V \leqslant EV_{DD} \leqslant 5.5V$	31.25	-	62.5	-	ns
SCLKp cycle	Τ	T _{KCY1} ≥	$2.7V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5 \text{V}$	41.67	-	83.33	-	ns
time	T _{KCY1}	2/F _{CLK}	$2.4V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5 \text{V}$	65	-	125	-	ns
			$2.0V \leqslant EV_{DD} \leqslant 5.5V$	125	-	250	-	ns
SCLKp	Tĸнı,Tĸ∟ı	$4.0V \leq EV_{DD} \leq 5.5V$		Тксү1/2-4	-	Тксү1/2-7	-	ns
		$2.7V \leqslant EV_{DD} \leqslant 5.5V$		T _{KCY1} /2-5	-	Т _{КСҮ1} /2-10	-	ns
high/low level width		$2.4V \leqslant EV_{DD} \leqslant 5.5V$		T _{KCY1} /2-10	-	T _{KCY1} /2-20	-	ns
level width		2.0V ≤ EV	$2.0V \leqslant EV_{DD} \leqslant 5.5V$		-	Тксү1/2-38	-	ns
SDIp		$4.0V \leq EV$	$V_{\rm DD} \leqslant 5.5 V$	12	-	23	-	ns
preparation	Ŧ	2.7V ≤ EV	$V_{\rm DD} \leqslant 5.5 V$	17	-	33	-	ns
time (to	T _{SIK1}	2.4V ≤ EV	$V_{\rm DD} \leqslant 5.5 V$	20	-	38	-	ns
SCLKp↑).		2.0V ≤ EV	$V_{\rm DD} \leqslant 5.5 V$	28	-	55	-	ns
SDIp hold								
time	TKSI1	$2.0V \leq EV$	/ _{DD} ≪ 5.5V	5	-	10	-	ns
(to SCLKp↑).								
$SCLKp{\downarrow}{\rightarrow}$								
SDOp	T _{KSO1}	$2.0V \le EV$	/ _{DD} ≪ 5.5V		5		10	20
output delay	TKSO1	C=20pF No	C=20pF Note1		5	-	10	ns
time								

2) Three-wire SPI mode (master mode, internal clock output). $40, 125^{\circ} C, 2, 0 V \le E V_{22} = V_{22} \le E E V V_{22} = E V_{2}$

Note1: C is the load capacitance of the SCLKp, SDOp output line.

Note: The SDIp pin is selected as the usual input buffer and the SDOp pin and SCLKp pin are selected as

the usual output mode through the port input mode register and the port output mode register.



Three-wire SPI mode (slave mode, external clock input). (T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

ltere	O wash a l	Condition		-40~85°C		85~125°C		1.1
Item	Symbol			Min	Max	Min	Max	Unit
SCLKp cycle time		$4.0V \leq EV_{DD}$	20MHz <f<sub>MCK</f<sub>	8/Fмск	-	16/Fмск	-	ns
		≤ 5.5V	F _{MCK} ≪20MHz	6/Fмск		12/Fмск	-	ns
	Тксү2	$2.7V \leq EV_{DD}$	16MHz <f<sub>MCK</f<sub>	8/Ғмск	-	16/Ғмск	-	ns
		≤ 5.5V	F _{MCK} ≪16MHz	6/Ғмск	-	12/Fмск	-	ns
		$2.4V \leq EV_{DD} \leq 5.5V$		6/F _{MCK} and ≥500	-	12/F _{MCK} and ≥1000	-	ns
		$2.0V \leq EV_{DD} \leq 5.5V$		6/F _{мск} and ≥750	-	12/F _{MCK} and ≥1500	-	ns
SCLKp	Turin	$4.0V \leq EV_{DD} \leq$	5.5V	Тксү1/2-7	-	Тксү1/2-14	-	ns
high/low	Ткн2 Типа	$2.7V \leqslant EV_{DD} \leqslant 5.5V$		Тксү1/2-8	-	Тксү1/2-16	-	ns
level width	T _{KL2}	$2.0V \leq EV_{DD} \leq$	5.5V	Тксү1/2-18	-	Тксү1/2-36	-	ns
SDIp		$2.7V \leq EV_{DD} \leq 5.5V$ $2.0V \leq EV_{DD} \leq 5.5V$		1/Fмск+20	-	1/Fмск+40		ns
preparation time (to SCLKp↑).	Тык2			1/F _{мск} +30	-	1/Fмск+60		ns
SDIp hold time (to SCLKp↑).	T _{KSI2}	$2.0V \leq EV_{DD} \leq 5.5V$		1/F _{мск} +31	-	1/Fмск+62	-	ns
SCLKp↓ →		$\begin{array}{l} 2.7 V \leqslant EV_{DD} \leqslant 5.5 V \\ C=30 pF^{Note1} \end{array}$		-	2/F _{мск} + 44	-	2/F _{мск} + 66	ns
SDOp output	T _{KSO2}	$2.4V \le EV_{DD} \le 5.5V$ C=30pF ^{Note1}		-	2/F _{мск} + 75	-	2/F _{мск} + 113	ns
delay time		$\begin{array}{l} 2.0 V \leqslant EV_{DD} \leqslant 5.5 V \\ C=30 pF^{Note1} \end{array}$		-	2/F _{мск} + 100	-	2/F _{мск} + 150	ns

Note1: C is the load capacitance of the SCLKp and SDOp output lines.

Note: The SDIp pin and SCLKp pin are selected as the usual input buffers and the SDOp pin is selected as the usual output mode through the port input mode register and the port output mode register.



4)	Four-wire SPI mode	(slave mode,	external clock in	nput).
----	--------------------	--------------	-------------------	--------

ltom	Sumbol	Condition		, -40~85°C		85~125°C		Unit
Item	Symbol			Min	Max	Min	Max	Unit
SSI00 settling time	Tssik	DAPmn=0	$2.7V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5 \text{V}$	120	-	240	-	ns
			$2.0V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5\text{V}$	200	-	400	-	ns
		DAPmn=1	$2.7V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5 \text{V}$	1/F _{MCK} +120	-	1/F _{MCK} +240	-	ns
			$2.0V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5\text{V}$	1/F _{MCK} +200	-	1/F _{MCK} +400	-	ns
SSI00 hold time	Tĸssi	DAPmn=0	$2.7V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5 \text{V}$	1/Fмск+120	-	1/Fмск+240	-	ns
			$2.0V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5\text{V}$	1/F _{MCK} +200	-	1/F _{MCK} +400	-	ns
		DAPmn=1	$2.7V \leqslant EV_{DD} \leqslant 5.5V$	120	-	240	-	ns
			$2.0V \leqslant \text{EV}_{\text{DD}} \leqslant 5.5\text{V}$	200	-	400	-	ns

(T_A= -40~125°C.2.0V≤EV_{DD}=V_{DD}≤5.5V.V_{SS}=EV_{SS}=0V)

Note: The SDIp pin and SCLKp pin are selected as the usual input buffers and the SDOp pin is selected as the usual output mode through the port input mode register and the port output mode register.



5) Simple IIC mode

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

ltere	O maked	Condition	-40~8	5°C	85~125°C		Linit
Item	Symbol	Condition Min		Max	Min	Max	Unit
	Fscl	$2.7V \leqslant EV_{DD} \leqslant 5.5V$ $C_{b} = 50 \; pF, \; R_{b} = 2.7K\Omega$	-	1000 Note1	-	400 Note1	kHz
SCLr clock frequency		$2.0V \leqslant EV_{DD} \leqslant 5.5V$ $C_b = 100 \text{ pF}, R_b = 3K\Omega$	-	400 Note1	-	100 Note1	kHz
		$2.0V \leqslant EV_{DD} \leqslant 2.7V$ $C_b = 100 \ pF, \ R_b = 5K\Omega$	-	300 Note1	-	75 Note1	kHz
	TLOW	$\begin{array}{l} 2.7 V \leqslant EV_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, \; R_{b} = 2.7 K \Omega \end{array}$	475	-	1200	-	ns
When SCLr is low hold time		$\begin{array}{l} 2.0 V \leqslant EV_{DD} \leqslant 5.5 V \\ C_{b} = 100 \; pF, R_{b} = 3 K \Omega \end{array}$	1150	-	4600	-	ns
		$\label{eq:constraint} \begin{array}{l} 2.0 V \leqslant E V_{DD} \leqslant 2.7 V \\ \\ C_{b} = 100 \; pF, \; R_{b} = 5 \; K \Omega \end{array}$	1550	-	6500	-	ns
	Тнідн	$\label{eq:constraint} \begin{array}{l} 2.7 V \leqslant E V_{DD} \leqslant 5.5 V \\ \\ C_{b} = 50 \; pF, \; R_{b} = 2.7 \; K \Omega \end{array}$	475	-	1200	-	ns
When SCLr is high hold time		$\begin{array}{l} 2.0V \leqslant EV_{DD} \leqslant 5.5V \\ C_{b} = 100 \; pF, R_{b} = 3 \; K\Omega \end{array}$	1150	-	4600	-	ns
		$\begin{array}{l} 2.0 V \leqslant E V_{DD} \leqslant 2.7 V \\ \\ C_{b} \texttt{=} 100 \; pF, \; R_{b} \texttt{=} 5 K \Omega \end{array}$	1550	-	6500	-	ns
Data settling time (received)	Tsu: dat	$\begin{array}{l} 2.7 V \leqslant EV_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, R_{b} = 2.7 K \Omega \end{array}$	1/F _{MCK} +85 _{Note2}	-	1/F _{MCK} +220 _{Note2}	-	ns
		$\begin{array}{l} 2.0 V \leqslant EV_{DD} \leqslant 5.5 V \\ C_{b} = 100 \; pF, R_{b} = 3 K \Omega \end{array}$	1/F _{MCK} +145 _{Note2}	-	1/F _{MCK} +580 _{Note2}	-	ns
		$\label{eq:constraint} \begin{array}{l} 2.0 V \leqslant E V_{DD} \leqslant 2.7 V \\ \\ C_{b} = 100 \; pF, \; R_{b} = 5 K \Omega \end{array}$	1/F _{MCK} +230 _{Note2}	-	1/F _{MCK} +1200 _{Note2}	-	ns
Data Hold Time (Send)	Thd: dat	$\begin{array}{l} 2.7 V \leqslant EV_{DD} \leqslant 5.5 V \\ C_{b} = 50 \; pF, \; R_{b} = 2.7 K \Omega \end{array}$	-	305	-	770	ns
		$\label{eq:constraint} \begin{array}{l} 2.0V \leqslant EV_{DD} \leqslant 5.5V \\ \\ C_{b} = 100 \ pF, \ R_{b} = 3K\Omega \end{array}$	-	355	-	1420	ns
		$\begin{array}{l} 2.0 V \leqslant E V_{DD} \leqslant 2.7 V \\ \\ C_{b} = 100 \ pF, \ R_{b} = 5 K \Omega \end{array}$	-	405	-	2070	ns

Note1: Must be set to at least F_{MCK}/4.

Note2: The setpoint of FMCK cannot exceed the hold time of SCLr="L" and SCLr="H".



6.7.2 Serial Interface IICA

1) I²C standard mode

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

Item	Sumb al	Condition	Specifica	Linit	
item	Symbol	Condition	Min	Max	Unit
SCLAr clock frequency	Fscl	Standard mode: $F_{CLK} \ge 1MHz$	-	100	kHz
The time at which the startup condition was established	Tsu: sta	-	4.7	-	us
Hold time of the startup condition	Thd: sta	-	4.0	-	us
When SCLAr is low, hold time	T _{LOW}	-	4.7	-	us
When SCLAr is high, the hold time is high	Тнідн	-	4.0	-	us
Data settling time (received)	TSU: DAT	-	250	-	ns
Data Hold Time (Send) Note2	T _{HD: DAT}	-	0	3.45	us
The time at which the stop condition was established	Tsu: sto	-	4.0	-	us
Bus idle time	T _{BUF}	-	4.7	-	us

Note1: Generates the first clock pulse after the start condition or restart condition is generated.

Note2: The maximum value of T_{HD}. _{DAT} (MAX.) needs to be guaranteed during normal transmission, and it is necessary to wait when performing a reply (ACK).

Note: The values of C_b (communication line capacitance) for each mode and R_b (pull-up resistance value of communication line) at this time are as follows:

Standard mode: Cb=400pF, Rb=2.7k Ω



2) I²C fast mode

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

ltom	Symbol	Condition	Specificat	Unit	
Item	Symbol	Condition	Min	Max	Unit
SCLAr clock frequency	F _{SCL}	Quick Mode: $F_{CLK} \ge 3.5 MHz$	-	400	KHz
The time at which the startup condition was established	Tsu: sta	-	0.6	-	us
Hold time of the startup condition Note1	THD: STA	-	0.6	-	us
When SCLAr is low, hold time	T _{LOW}	-	1.3	-	us
When SCLAr is high, the hold time is high	Тнідн	-	0.6	-	us
Data settling time (received)	T _{SU: DAT}	-	100	-	ns
Data Hold Time (Send) Note2	THD: DAT	-	0	0.9	us
The time at which the stop condition was established	Tsu: sto	-	0.6	-	us
Bus idle time	T _{BUF}	-	1.3	-	us

Note1: Generates the first clock pulse after the start condition or restart condition is generated.

Note2: The maximum value of T_{HD: DAT} (MAX.) needs to be guaranteed during normal transmission, and it is necessary to wait when performing a reply (ACK).

Note: The values of C_b (communication line capacitance) for each mode and R_b (pull-up resistance value of communication line) at this time are as follows:

Fast mode: C_b=320pF, R_b=1.1kΩ



3) I²C Enhanced Quick Mode

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

ltom	Symbol	Condition	Specificat	Unit		
Item	Symbol	Condition	Min	Max	Unit	
SCLAr clock frequency	Fscl	Enhanced Quick Mode: $F_{CLK} \ge 10MHz$	-	1000	KHz	
The time at which the startup condition was established	TSU: STA	-	0.26	-	us	
Hold time of the startup condition Note1	THD: STA	-	0.26	-	us	
When SCLAr is low, hold time	TLOW	-	0.5	-	us	
When SCLAr is high, the hold time is high	Тнідн	-	0.26	-	us	
Data settling time (received)	T _{SU: DAT}	-	50	-	ns	
Data Hold Time (Send) Note2	THD: DAT	-	0	0.45	us	
The time at which the stop condition was established	Tsu: sto	-	0.26	-	us	
Bus idle time	T _{BUF}	-	0.5	-	us	

Note1: Generates the first clock pulse after the start condition or restart condition is generated.

Note2: It is necessary to guarantee tHD: The maximum value of DAT (MAX.) during normal transmission, and it is necessary to wait when performing a reply (ACK).

Note: The values of C_b (communication line capacitance) for each mode and R_b (pull-up resistance value of communication line) at this time are as follows:

Enhanced Quick Mode: $C_b=120pF$, $R_b=1.1k\Omega$



6.8 Analog Characteristics

6.8.1 A/D Converter Features

Differentiation of A/D converter characteristics

Reference voltage	Reference voltage(+)=AV _{REFP} Reference voltage(-)=AV _{REFM}	Reference voltage(+)=V _{DD} Reference voltage(-)=V _{SS}
ANIO~ ANI15		
The internal reference voltage, the output	Refer to 6.8.1(1).	Refer to 6.8.1 (2).
voltage of the temperature sensor		

Select the case for reference voltage(+)=AV_{REFP} /ANI0 and reference voltage(-)=AV_{REFM} /ANI1 (T_A= -40~125°C,2.0V≤AV_{REFP}≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=0V,Reference voltage(+)=AV_{REFP}, Reference

VOItage(-)=AV _{REFM} =UV)										
Item	Symbol	Condi	tion	Min	Тур	Max	Unit			
resolution	RES	-		-	12	-	bit			
Combined error Note1	ET	12-bit resolution	$2.0V \leqslant \! AV_{REFP} \leqslant 5.5V$	-	3	-	LSB			
Zero scale error Note1	Ezs	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-	0	-	LSB			
Full scale error Note1	E _{FS}	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-	0	-	LSB			
Integral linearity error	EL	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-1	-	1	LSB			
Differential linearity error Note1	ED	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-1.5	-	1.5	LSB			
Conversion time Note3		12-bit resolution Conversion objects: ANI2~ ANI15	$2.0V \leq V_{DD} \leq 5.5V$	45	-	-	1/F _{ADC}			
	T _{CONV}	12-bit resolution Conversion objects: internal reference voltage, temperature sensor output voltage, PGA output voltage	$2.0V \leq V_{DD} \leq 5.5V$	72	-	-	1/Fadc			
External input resistance	RAIN	$R_{AIN} < (Ts / (F_{ADC} x C_{ADC}))$	x In(2 ¹²⁺²)) - R _{ADC})	-	7.5 Note4	-	KΩ			
Sampling switch resistance	RADC	-		-	-	1.5	KΩ			
Sample-and-hold capacitor	CADC	-		-	2	-	pF			
		ANI2~ ANI15		0	-	AV_{REFP}	V			
Analog input voltage	VAIN	Internal reference voltage (2.0V≪V _{DD} ≪5.5V))		VBGR Note2	2	V			
	red error Note1 ET ale error Note1 Ezs ale error Note1 EFs linearity error Note1 EL ntial linearity ror Note1 ED sion time Note3 TCONV ernal input sistance RAIN sistance RADC le-and-hold apacitor CADC	The output voltage of the temperature sensor (2.0V \leq V _{DD} \leq 5.5V)			V _{TMPS25} Not	e2	V			

voltage(-)=AV_{REFM}=0V)

Note1: Does not contain quantization errors (\pm 1/2 LSB).

Note2: Please refer to " 6.8.2 Characteristics of Temperature Sensors/Internal Reference Voltages".

Note3: F_{ADC} is the operating frequency of AD, and the maximum operating frequency is 48MHz.

Note4: Guaranteed by design, mass production is not tested. The typical value is the default sampling period Ts=13.5, and the conversion speed is the calculated value at F_{ADC} =48MHz.

(2) Select the case of reference voltage $(+) = V_{DD}$ and reference voltage $(-) = V_{SS}$

 $(T_{\text{A}}=-40\sim125^{\circ}\text{C}, 2.0\text{V} \leqslant \text{EV}_{\text{DD}}=\text{V}_{\text{DD}} \leqslant 5.5\text{V}, \text{V}_{\text{SS}}=\text{EV}_{\text{SS}}=0\text{V}, \text{Reference Voltage(+)}=\text{V}_{\text{DD}},$

Item	Symbol	, ,	ion	Min	Тур	Max	Unit
resolution	RES	-		-	12	-	bit
Combined error Note1	ET	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-	-	-	LSB
Zero scale error Note1	Ezs	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-	-	-	LSB
Full scale error Note1	E _{FS}	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-	-	-	LSB
Integral linearity error Note1	EL	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-2	-	2	LSB
Differential linearity error Note1	ED	12-bit resolution	$2.0V \leq AV_{REFP} \leq 5.5V$	-3	-	3	LSB
	Тсолу	12-bit resolution Conversion objects:	2.0V≪V _{DD} ≪5.5V	45	-	-	1/fadc
Conversion time Note3		12-bit resolution Conversion objects: internal reference voltage, output voltage of	2.0V≪V _{DD} ≪5.5V	72	-	-	1/fadc
External input resistance	R _{AIN}	${\sf R}_{\sf AIN}<({\sf Ts}/({\sf F}_{\sf ADC}{\sf x}{\sf C}_{\sf ADC}{\sf x})$	put voltage of $N < (Ts / (F_{ADC} x C_{ADC} x ln(2^{12+2})) - R_{ADC})$		7.5 Note4	-	kΩ
Sampling switch resistance	RADC	-		-		1.5	kΩ
Sample-and-hold capacitor	CADC	-		-	2		pF
		ANIO~ ANI7		0		Vdd	V
		ANI8~ ANI15		0		EV_DD	V
Note1 Differential linearity error Note1 Conversion time Note3 External input resistance Sampling switch resistance Sample-and-hold	VAIN	Internal reference voltage (2.0V≤V _{DD} ≤5.5V)			V _{BGR} Note2	2	V
		The output voltage of the te (2.0V≪V _{DD} ≪5.5V)	emperature sensor		VTMPS25 ^{Note}	- - - - 2 3 - - - - 1.5 VDD EVDD	V

Reference Voltage (-) =V_{SS})

Note1: Does not contain quantization errors (\pm 1/2 LSB).

Note2: Please refer to " 6.8.2 Characteristics of Temperature Sensors/Internal Reference Voltages".

Note3: FADC is the operating frequency of AD, and the maximum operating frequency is 48MHz.

Note4: Guaranteed by design, mass production is not tested. The typical value is the default sampling period Ts=13.5, and the conversion speed is $F_{ADC}=64MHz$.



6.8.2 Characteristics of The Temperature Densor/Internal Reference

Voltage

Item	Symbol	Condition	Min	Тур	Max	Unit
The output voltage of the	VTMPS25	T₄=25°C		1.09		V
temperature sensor	V TMPS25	I A=25 C	-	1.09	-	v
	V _{BGR}	T _A = -40~10°C	1.25	1.45	1.65	V
Internal reference voltage		T _A =10~70°C	1.38	1.45	1.50	V
		T _A =70~125°C	1.35	1.45	1.55	V
Temperature coefficient	FVTMPS	-	-	-3.5	-	mV/°C
Run stable wait time	Тамр	-	5	-	-	ms

Remark: Low temperature specification value is guaranteed by the design, and low temperature conditions are not measured in mass production.

6.8.3 D/A Converter

(T _A = -40~125°C,2.0V≤EV _{DD} =V _{DD} ≤5.5V,V _{SS} =EV _{SS} =0V)	

Item	Symbol		Condition			Max	Unit
resolution	RES	-	-	-	-	8	bit
Combined error	ET	Rload=4MΩ	$2.0V \leq V_{DD} \leq 5.5V$	-2.5	-	2.5	LSB
Stabilization	T	Cload 20pF	2.7V≤V _{DD} ≤5.5V	-	-	3	ms
time	T _{SET}	T _{SET} Cload=20pF	2.0V≤V _{DD} <2.7V	-	-	6	ms
Output impedance	RO	Rload=4MΩ	2.0V≤V _{DD} ≤5.5V	4.7	-	8	KΩ

Remark: Low temperature specification value is guaranteed by the design, and low temperature conditions are not measured in mass production.



6.8.4 Comparator

Item	Symbol		Condition	Min	Тур	Max	Unit
Input deviation voltage	Voffset	-		-	±10	±40	mV
Input voltage range	VIN	-		0	-	V _{DD}	V
Internal reference	ΔV_{IREF}	CmRVM regist	ter: 7FH ~ 80H (m = 0, 1).	-	-	±2	LSB
voltage deviation	ΔVIREF	other		-	-	±1	LSB
Response time	Tcr, Tcf	The input amp	litude ± 100mV	-	70	125	ns
Run settling time Note1	Т _{STB}		V _{DD} = 3.3 ~ 5.5V	-	-	1	-
Run settling time have		CMPn=0->1 V _{DD} = 2.0 ~ 3.3V		-	-	3	ms
Reference settling time	Tvr	CVRE=0->1 Note2		-	-	20	ms
Operating current	ICMPDD	Refer to 6.5.2	Supply current characterist	ics		•	-

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

Note 1: The time required from comparator action enable (CMPnEN=0->1) to meeting the various DC/AC style requirements of the CMP.

Note2: By setting the CVREm bit to 1; m = 0 to 1), the reference settling time is passed before the comparator output can be enabled (CnOE bit = 1; n = 0 to 1)



6.8.5 Programmable Gain Amplifier PGA

Parameter	Symbol	≦EV _{DD} =V _{DD} ≤5.5V,` (Condition	Min	Тур	Max	Unit
Input deviation voltage	Viopga		-	-	-	±10	mV
Input voltage range	VIPGA		-	0	-	0.9xV _{DD} /Gain	V
Output voltage	VIOHPGA		-	0.93xV _{DD}	-	-	V
range	VIOLPGA		-	-	-	0.07xV _{DD}	V
		x4	-	-	-	±1	%
		x8	-	-	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	%	
		x10	-	-	-	±1	%
Gain deviation		x12	-	-	-	±2	%
		x14	-	-	-	±2	%
		x16	-	-	-	±2	%
		x32	-	-	-	±3	%
		4.0 V \leq V _{DD} \leq 5.5V (other than x32)	3.5	-	-		
	SR _{RPGA}	0.9V _{DD} /gain. 10 to	$4.0~\textrm{V} \leqslant \textrm{V}_\textrm{DD} \leqslant 5.5\textrm{V}~\textrm{(x32)}$	3.0	-	+1 +2 +2 +2 +3 - - - - - - - - - - - - - - -	
		90% of output voltage amplitude	$2.0~V \leqslant V_{DD} \leqslant 4.0V$	0.5	-	-	
Conversion rate		Falling Vin= 0.1V _{DD} /gain to	$4.0V \leqslant V_{DD} \leqslant 5.5V$ (other than x32)	3.5	-	<pre>±10</pre>	V/us
	SR _{FPGA}	0.9V _{DD} /gain. 90 to	$4.0V \leqslant V_{DD} \leqslant 5.5V$ (x32)	3.0	-	-	
		10% of output voltage amplitude	$2.0V \leqslant V_{DD} \leqslant 4.0V$	0.5	-	<pre>±10 .0.9xV_{DD}/Gain</pre>	
		x4	-	-	-	5	us
		x8	-	-	-	 ±10 0.9xV_{DD}/Gain - 0.07xV_{DD} ±1 ±1 ±1 ±2 ±2 ±2 ±2 ±3 - -	us
Due o tille s	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	5	us				
Run settling time ^{Note1}	T _{PGA}	x12	-	-	-	± 10 0.9xV _{DD} /Gain - 0.07xV _{DD} ± 1 ± 1 ± 1 ± 2 ± 2 ± 2 ± 2 ± 2 ± 2 ± 2 ± 2 ± 2 5 5 5 5 10 10 10 10 10	us
		x14	-	-	-	10	us
		x16	-	-	-	10	us
		x32	-	-	-	± 10 0.9xV _{DD} /Gain - 0.07xV _{DD} ± 1 ± 1 ± 1 ± 2 ± 2 ± 2 ± 2 ± 2 ± 2 ± 2 5 5 5 5 5 10 10 10 10	us
Operating current	Ipgadd	Refer to 6.5.2 Sup	ply current characteristics				

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

Note1: The time required from PGA action enable (PGAEN=1) to meeting the various DC and AC style requirements of the PGA.

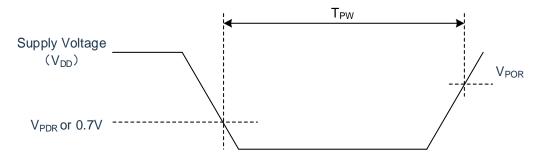


6.8.6 POR Circuit Characteristics

(T_A= -40~125°C,V_{SS}=0V)

Item	Symbol	Condition	Min	Тур	Max	Unit
Detection voltage	Vpor	When the supply voltage rises	-	1.60	2.0	V
	Vpdr	When the supply voltage drops	1.37	1.50	-	V
Minimum pulse width Note1	T _{PW}	-	300	-	-	μs

Note1: This is the time required for the POR to reset when V_{DD} is lower than V_{PDR}. In addition, in deep sleep mode, the bit0 (HIOSTOP) and bit7(MSTOP) stops the oscillation of the main system clock (F_{MAIN}) from V_{DD} below 0.7V to a rebound above V_{POR} The time required for reset up to POL.





6.8.7 LVD Circuit Characteristics

- (1) Reset mode and interrupt mode
 - (T_A= -40~125°C,V_{PDR}≤V_{DD}≤5.5V,V_{SS}=0V)

Item	Symbol	Condition	Min	Тур	Max	Unit
		When the supply voltage rises	-	4.06	4.26	V
	VLVD0	When the supply voltage drops	3.78	3.98	-	V
		When the supply voltage rises	-	3.75	-	V
	VLVD1	When the supply voltage drops	-	3.67	-	V
Detection		When the supply voltage rises	-	3.02	-	V
voltage	VLVD2	When the supply voltage drops	-	2.96	-	V
Vlvd3		When the supply voltage rises	-	2.71	-	V
		When the supply voltage drops	-	2.65	-	V
	N/	When the supply voltage rises	-	2.09	2.16	V
V _{LVD4}		When the supply voltage drops	1.97	2.04	-	V
Minimum pulse width	TLW	-	300	-	-	μs
Detection delay	-	-		-	300	μs

Remark: It is guaranteed by the design and not tested in mass production.

(2) Interrupt & reset mode

Item	Symbol	Condition				Тур	Max	Unit
	V _{LVDB0}	V _{POC2} =0	drop reset voltag	je	1.78	1.84	-	V
		V _{POC1} =0	LVIS1=0	Rise reset release voltage	-	2.09	2.16	V
	VLVDB2	VPOC0=1	LVIS0=1	Drop the interrupt voltage	1.97	2.04	-	V
	VLVDC0		drop reset voltag	je	-	2.45	-	V
	Vuence	V _{POC2} =0	LVIS1=0	Rise reset release voltage	-	2.71	-	V
Interrupt & reset	VLVDC2	VPOC1=1	LVIS0=1	Drop the interrupt voltage	-	2.65	-	V
		V _{POC0} =0	LVIS1=0	Rise reset release voltage	-	3.75	-	V
	VLVDC3	LVIS0=0	Drop the interrupt voltage	-	3.67	-	V	
	VLVDD0		down reset volta	ge	-	2.75	-	V
		V _{POC2} =0	LVIS1=0	Rise reset release voltage	-	3.02	-	V
	Vlvdd2	VPOC1=1	LVIS0=1	Drop the interrupt voltage	-	2.96	-	V
		V _{POC0} =1	LVIS1=0	Rise reset release voltage	-	4.06	4.26	V
	Vlvdd3		LVIS0=0	Drop the interrupt voltage	3.78	3.98	-	V



6.8.8 Reset Time Versus Rising Slope Characteristics of The Supply

Voltage

(T_A= -40~125°C,V_{SS}=0V)

Item	Symbol	Condition	Min	Тур	Max	Unit
Reset time	T _{RESET}	-	-	1	-	ms
The rising slope of the supply voltage	SVDD	-	-	-	54	V/ms



6.9 Memory Feature

6.9.1 Flash Memory Feature

(T _A = -40~125°C,2.0V≤EV _{DD} =V _{DD} ≤5.5V,V _{SS} =EV _{SS} =0V)

Parameter	Conditions	Min	Max	Unit
Word Program(32bit)	Program(32bit) $T_{A=} -40 \sim 125^{\circ}C$		30	μs
Sector erase	T _A = −40~125°C	4	5	ms
Chip erase	T _A = −40~125°C	20	40	ms
N_{END} Endurance $T_{A}=-40\sim125^{\circ}C$		20	-	kcycles
Data retention	20 kcycles Note1 at T _A =125°C	20	-	Years
	Word Program(32bit) Sector erase Chip erase Endurance	Word Program(32bit) $T_{A=} -40 \sim 125^{\circ}C$ Sector erase $T_{A=} -40 \sim 125^{\circ}C$ Chip erase $T_{A=} -40 \sim 125^{\circ}C$ Endurance $T_{A=} -40 \sim 125^{\circ}C$	Word Program(32bit) TA= -40~125°C 24 Sector erase TA= -40~125°C 4 Chip erase TA= -40~125°C 20 Endurance TA= -40~125°C 20	Word Program(32bit) TA= -40~125°C 24 30 Sector erase TA= -40~125°C 4 5 Chip erase TA= -40~125°C 20 40 Endurance TA= -40~125°C 20 -

Note1: Cycling performed over the whole temperature range.

Remark: It is guaranteed by the design and not tested in mass production.

6.9.2 RAM Memory Feature

(T_A= -40~125°C,2.0V≤EV_{DD}=V_{DD}≤5.5V,V_{SS}=EV_{SS}=0V)

Symbol	Parameter	Conditions	Min	Max	Unit
VRAMHOLD	RAM Hold Voltage	T _A = −40~125°C	0.8	-	V



6.10 Electrical Sensitivity Characteristics

6.10.1 Electrostatic Discharge (ESD) Feature

Symbol Parameter		Conditions	Class	
Vesd(HBM)	Electrostatic discharge voltage	T _A =25°C	ЗА	
	(human body model)	JEDEC EIA/JESD22- A114	SA	

Remark: It is guaranteed by the design and not tested in mass production.

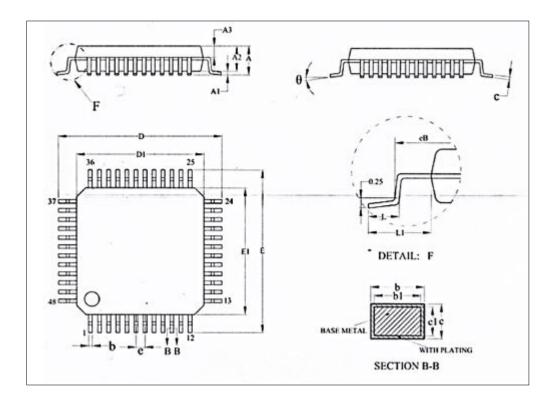
6.10.2 Static Latch-up (LU) Feature

Symbol	Parameter	Conditions	Class
LU	Static latch-up class	JEDEC STANDARD NO.78E NOVEMBER 2016	Class II A (T _A =125°C)



7 Package Information

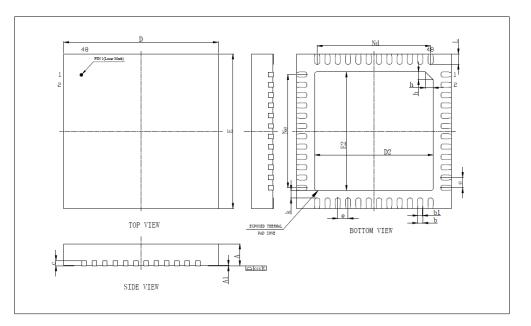
7.1 LQFP48(7x7mm, 0.5mm)



Or mark all		Millimetre	
Symbol	Min	Name	Max
А	-	-	1.60
A1	0.05	-	0.15
A2	1.35	1.40	1.45
A3	0.59	0.64	0.69
b	0.18	-	0.26
b1	0.17	0.20	0.23
С	0.13	-	0.17
c1	0.12	0.13	0.14
D	8.80	9.00	9.20
D1	6.90	7.00	7.10
E	8.80	9.00	9.20
E1	6.90	7.00	7.10
eB	8.10	-	8.25
е		0.50BSC	
L	0.45	-	0.75
L1		1.00REF	
θ	0°	-	7°



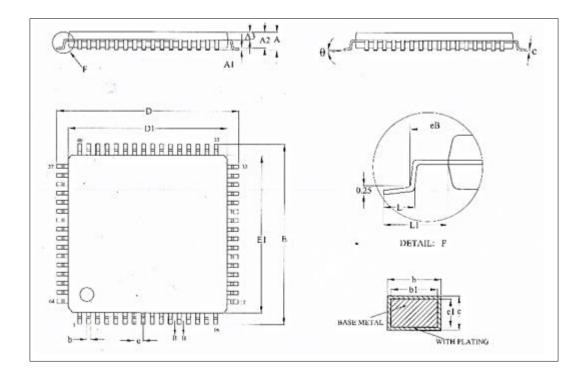
7.2 QFN48(6x6, 0.4mm)



Currente al		Millimeter				
Symbol	Min	Nom	Max			
A	0.70	0.75	0.80			
A1	0	0.02	0.05			
b	0.15	0.20	0.25			
b1	0.18REF					
с		0.203REF				
D	5.90	6.00	6.10			
D2	4.55	4.60	4.65			
е	0.40BSC					
Nd	4.40BSC					
Ne	4.40BSC					
E	5.90	6.00	6.10			
E2	4.55	4.60	4.65			
L	0.35	0.40	0.45			
h	0.25	0.30	0.35			
R		0.075REF				
k	0.25	0.30	0.35			
CCC		0.08				



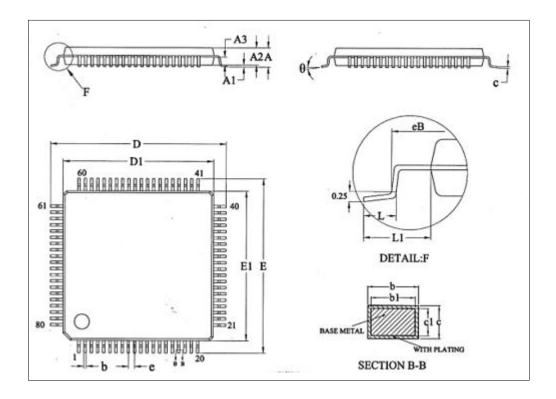
7.3 LQFP64(7x7, 0.4mm)



Cumphia		Millimetre	
Symbol	Min	Name	Max
A	-	-	1.60
A1	0.05	-	0.15
A2	1.35	1.40	1.45
A3	0.59	0.64	0.69
b	0.16	-	0.24
b1	0.15	0.18	0.21
С	0.13	-	0.17
c1	0.12	0.13	0.14
D	8.80	9.00	9.20
D1	6.90	7.00	7.10
E	8.80	9.00	9.20
E1	6.90	7.00	7.10
eB	8.10	-	8.25
е		0.40BSC	
L	0.45	-	0.75
L1		1.00REF	
θ	0°	-	7°



7.4 LQFP80(12x12, 0.5mm)



Symbol	Millimetre			
	Min	Name	Max	
A	-	-	1.60	
A1	0.05	-	0.15	
A2	1.35	1.40	1.45	
A3	0.59	0.64	0.69	
b	0.18	-	0.26	
b1	0.17	0.20	0.23	
С	0.13	-	0.17	
c1	0.12	0.13	0.14	
D	13.80	14.00	14.20	
D1	11.90	12.00	12.10	
E	13.80	14.00	14.20	
E1	11.90	12.00	12.10	
eB	13.05	-	13.25	
е	0.50BSC			
L	0.45	0.60	0.75	
L1	1.00REF			
θ	0°	-	7°	



8 Revision History

Revision	Date	Modify content	
V1.00	Aug 2022	Internal First Edition	
V1.01	Nov 2022	Modified the parameters in 6.5.1	
V1.0.2	Feb 2023	 Supplement the standard grade of automobile products in chapter 1.1 Supplement the remarks of parameters at low temperature Correct the product pin function description in section 4.1 Optimize format 	
V1.0.3	Mar 2023	 6.5.2 Supply Current Characteristics correct maximum parameter 1.3.4, 4.1.3 P137 Pin function SI00 corrected to SDI00 Corrected 7.4 package Information 	
V1.0.4	May 2023	Update 7.2 package Information	
V1.0.5	Sep 2023	 Update P150~P153 pin characteristics in 6.2,6.3,6.5.1 The 80pin pin encapsulates the P40 supplement (TXD0) function in the diagram 	
V1.0.6	Nov 2023	Updated Flash erase times in 6.9.1	
V1.0.7	Jan 2024	 Modified section 6.1 Typical Application of Peripheral Circuits Add input current parameters in section 6.3 Corrected the cover page Added P64~P67 support for internal pull-up function in section 4.1.3 Modified to the number of multiple PWM signals in section 5.13.2 	